

Networks for the IoT (Internet of Things)

Hardware considerations

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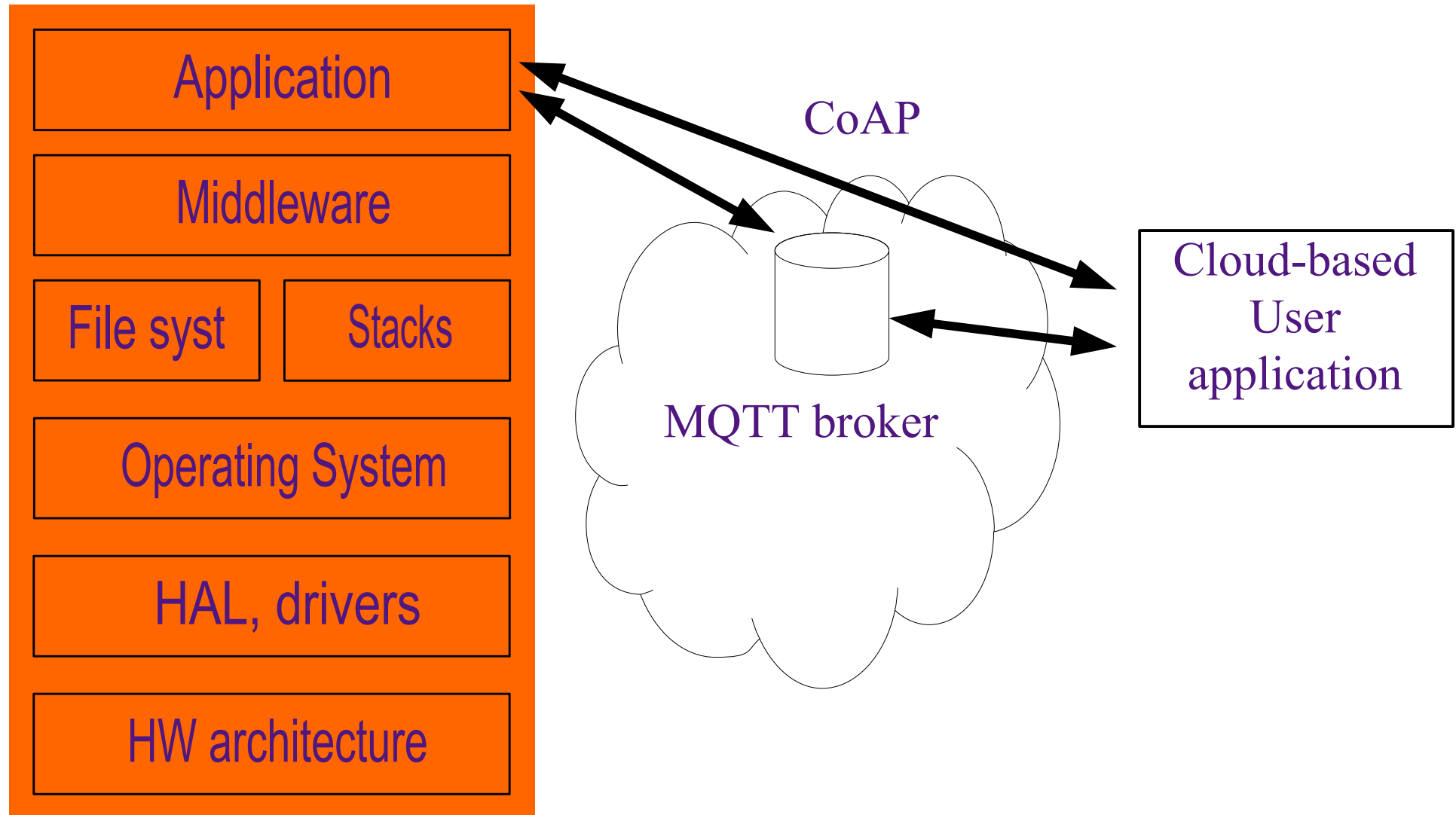
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Agenda

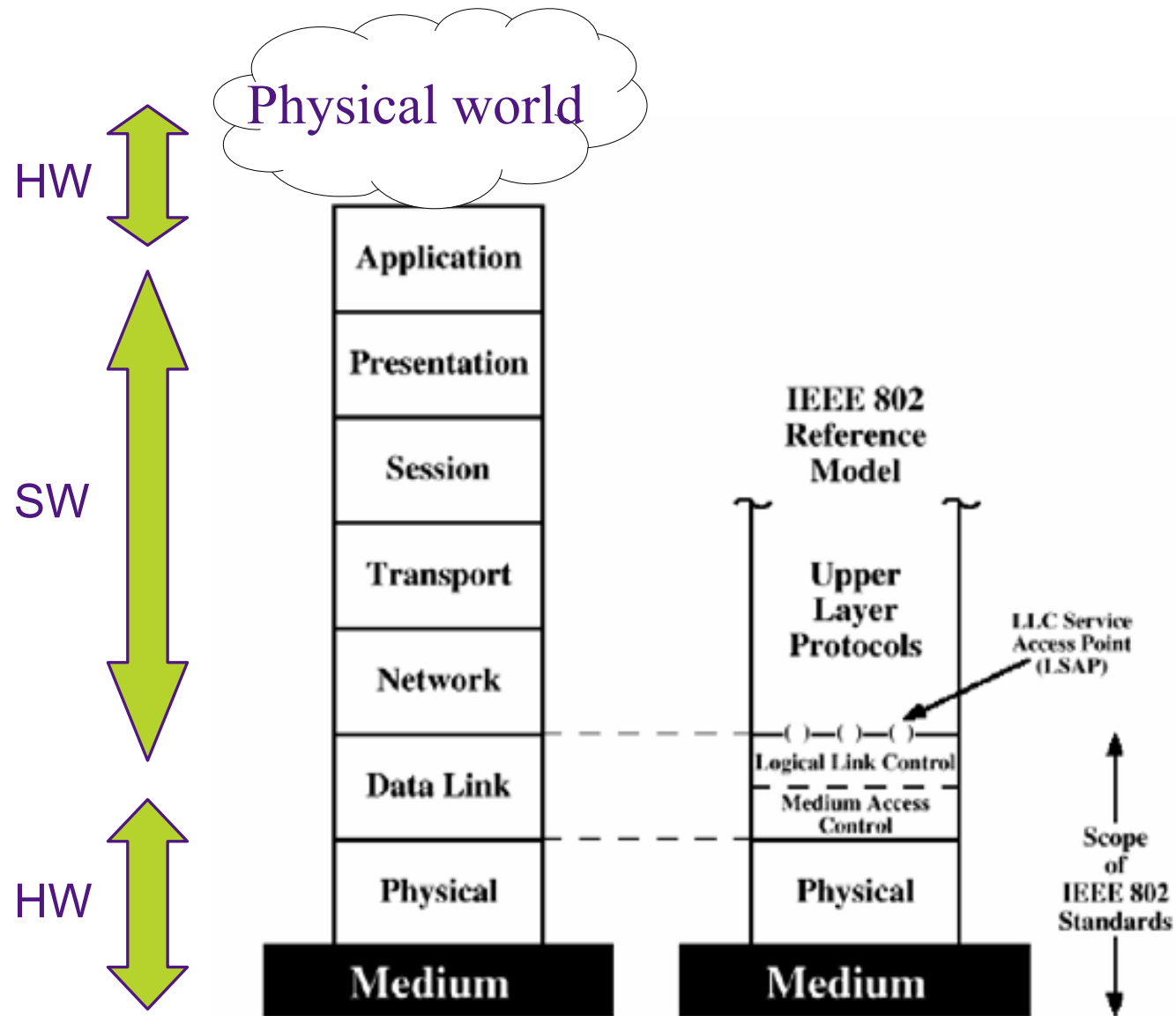
- Introduction
- Some experimentation boards and platforms
- Energy source, energy consumption
- Microcontrollers, memory
- Spectrum, PHY layer and radio chips
- Conclusions

Introduction

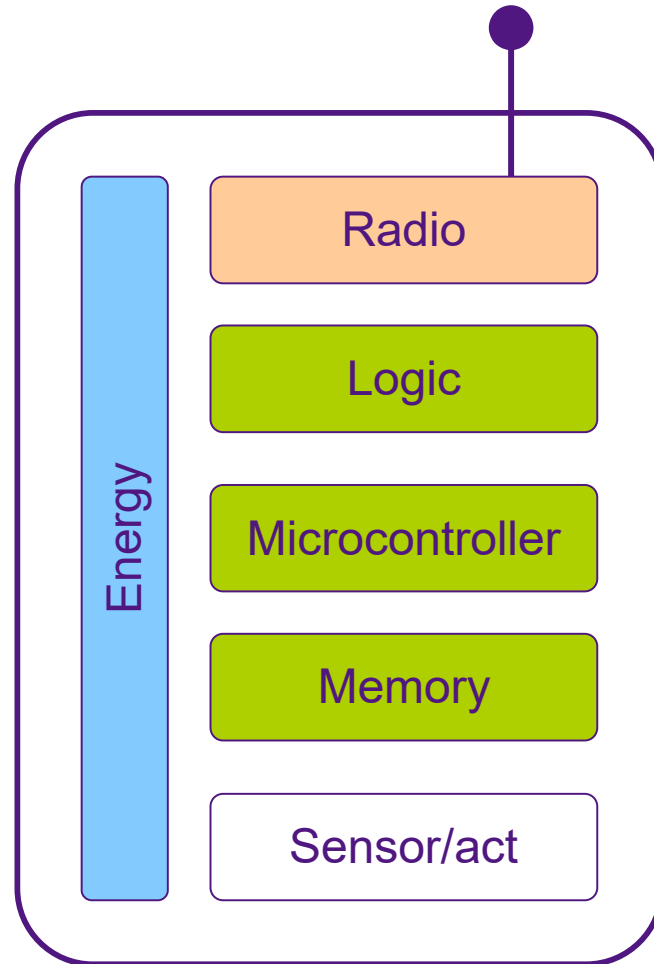
IoT not only a « software » issue



IoT device « networking » architecture



IoT device « hardware » architecture



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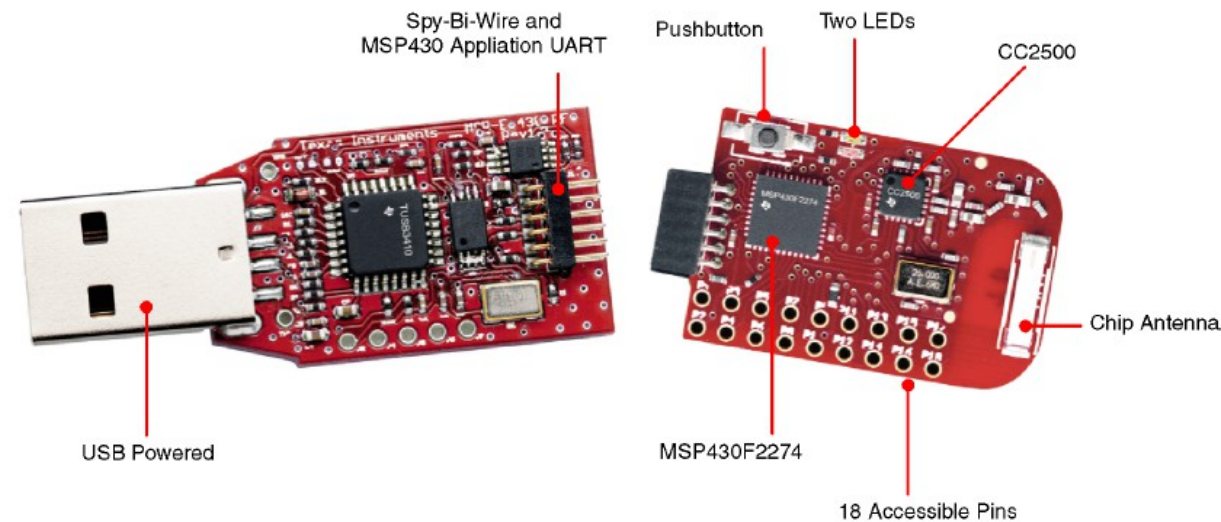
Experimentation boards and platforms

A range of boards

TI eZ430-RF2500

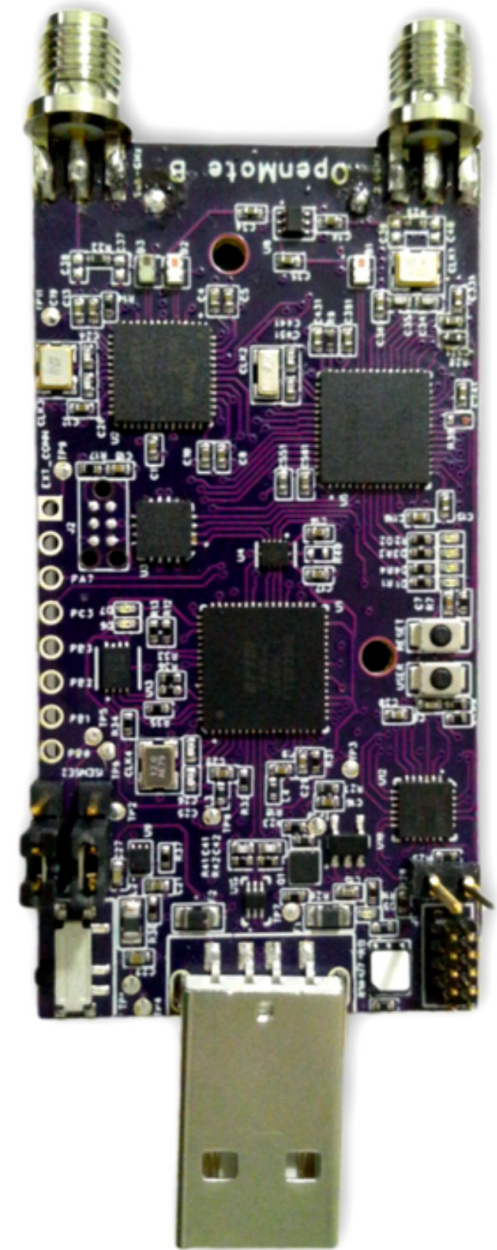
- TI starter kit

- MSP430F2274, 16 MHz RISC
 - 32 KB flash, 1 KB RAM
- CC2500 radio
 - IEEE 802.15.4 2.4 GHz compliant
- Ceramic chip antenna
- 50 m range LOS
- Temp sensor, push button, 2 LEDs
- Analogue and digital IOs
- USB interface for programming and data exchange



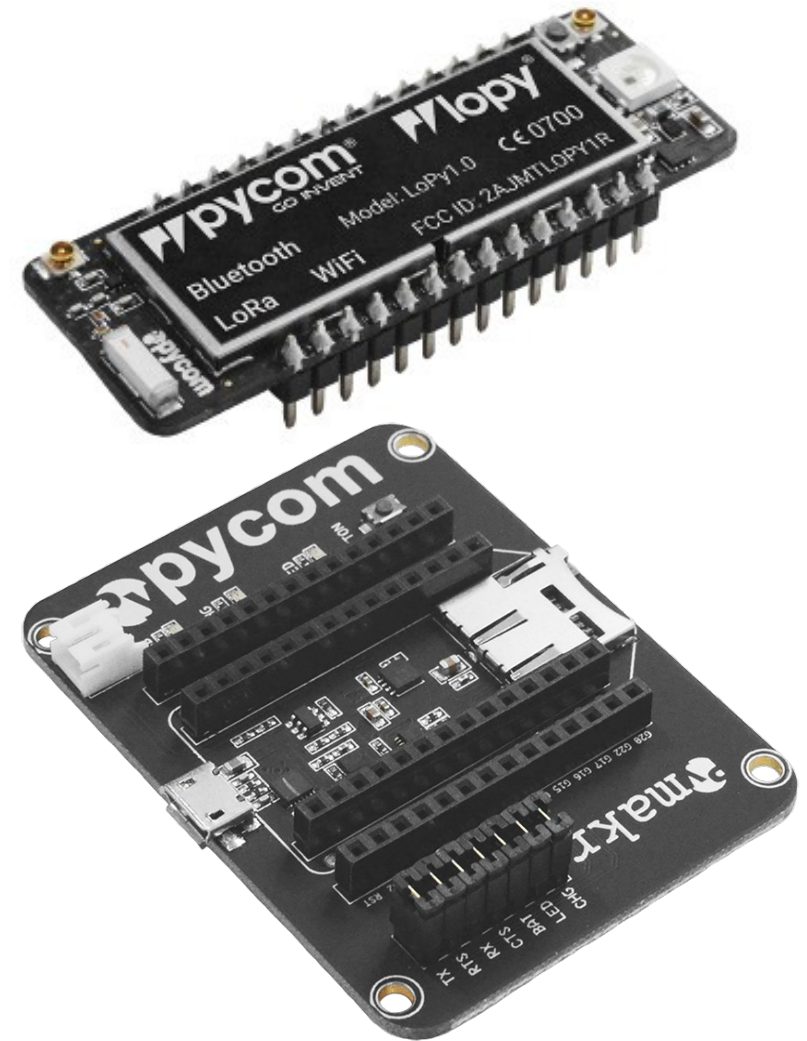
OpenMote-B

- TI CC2538 SoC
 - ARM Cortex M3
 - 512 KiB Flash, 32 KiB RAM
 - 2.4 GHz radio, IEEE 802.15.4 compliant
- Atmel RF86RF215 radio
 - 868/915 MHz and 2.4 GHz
 - supports all IEEE 802.15.4g modulations
- Temp/humidity sensor
- User button, 4 LEDs
- Current monitoring jumpers
- Contiki, RiOT, OpenWSN support



Pycom board

- ESP32 processor
- Native MicroPython interpreter
- File system, USB
- Interactive execution over serial port
- File synchronisation and detached execution
- Proprietary form factor and connector
- FiPy
 - Dual-core LX6 processor, ULP co-processor
 - 520 KB RAM, serial 8 MB Flash + 4 MB RAM
 - LTE-m/NB1 + Sigfox + LoRaWAN + BT4.2 + WiFi b/g/n

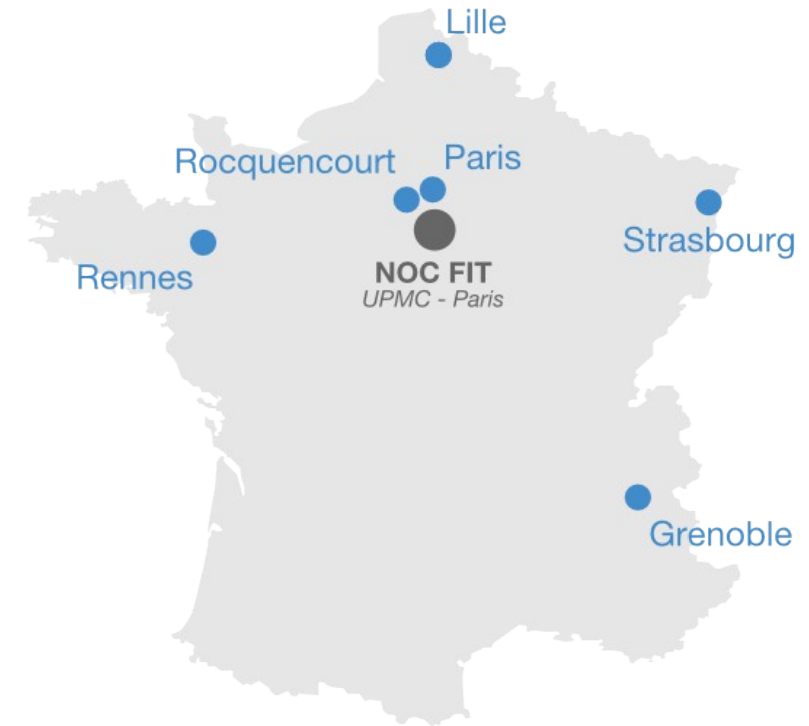


Large experimentation platforms

FIT/IoT-Lab platform

- opened Nov 2014
- 2700 nodes over 6 sites
- 4 diff. architectures
 - MSP430, Cortex M3, A8 processors
 - 868 MHz, 802.15.4 2.4 GHz radios
- some mobile nodes
 - trains, robots

www.iot-lab.info

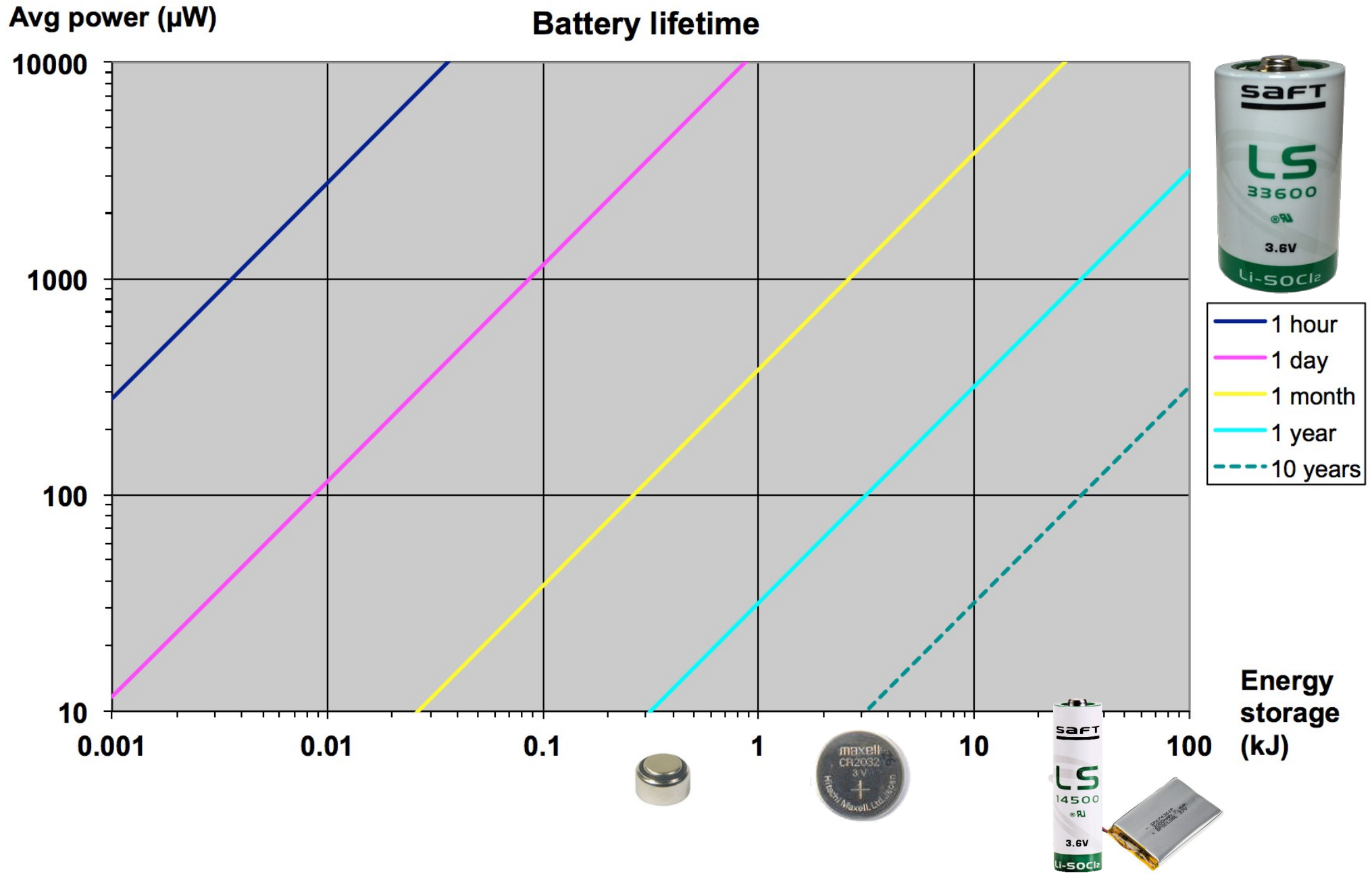


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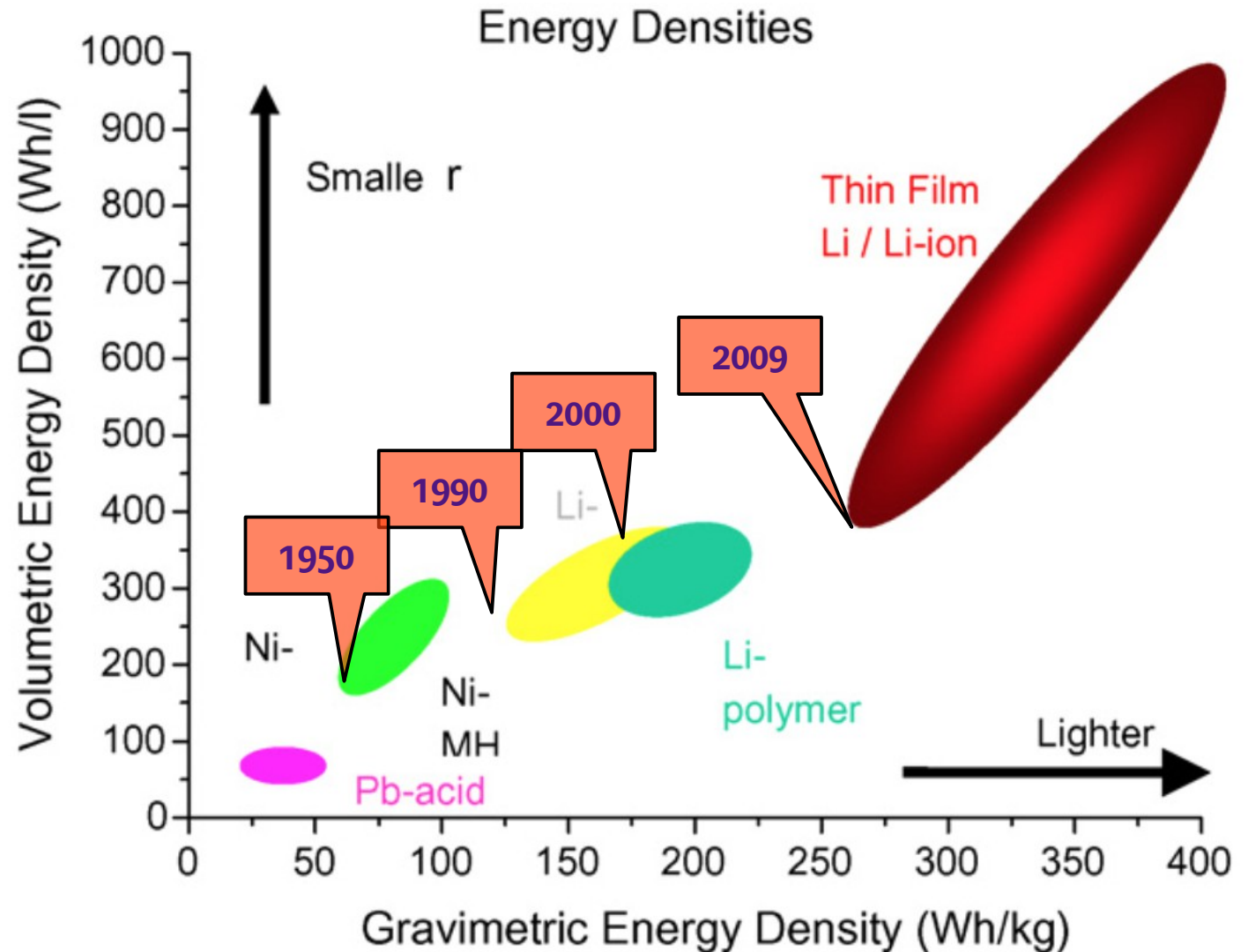
Energy source, energy consumption

Energy source for sensor node



Rechargeable batteries performance

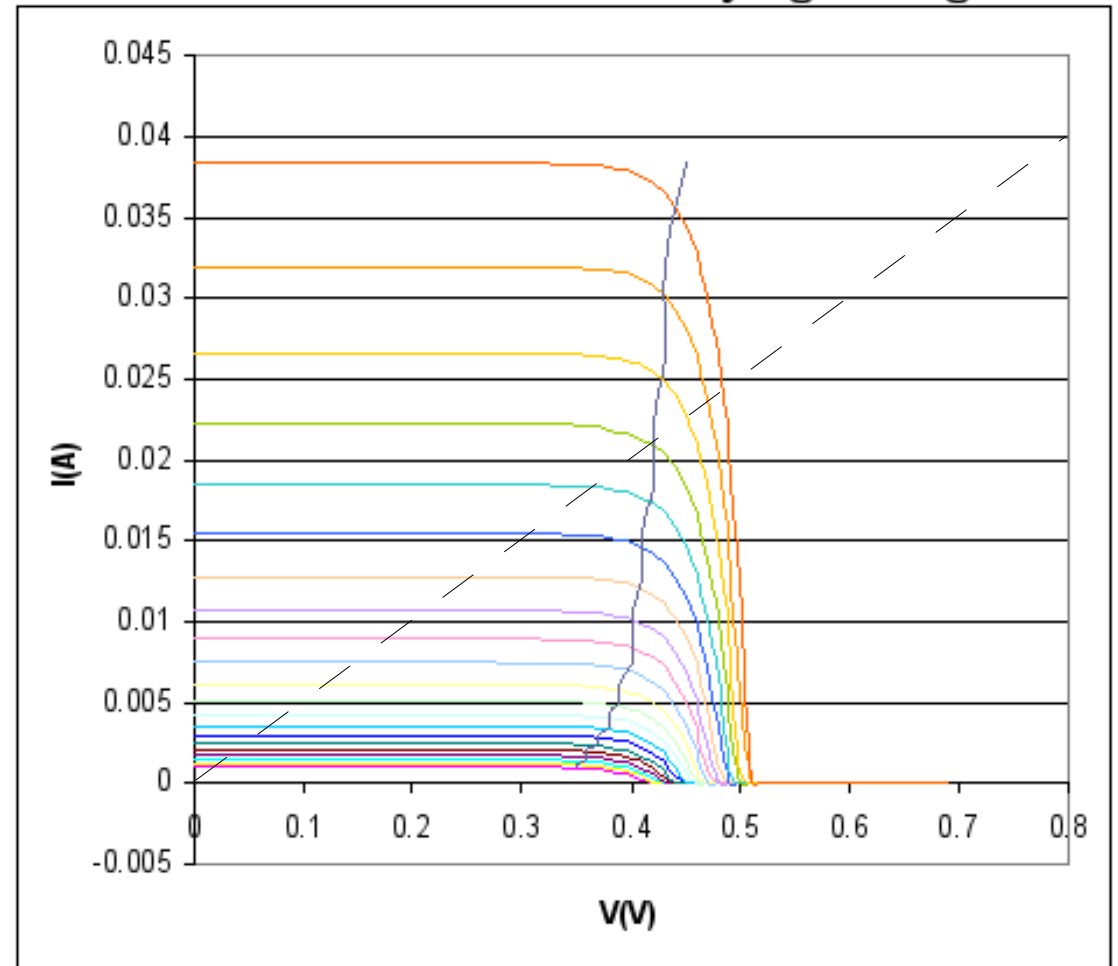
- Performance has doubled over two decades



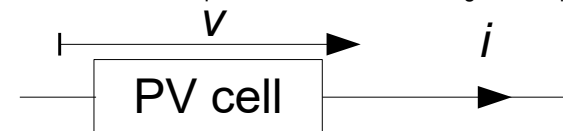
Solar energy harvesting

- Solar radiance
 - $1 \text{ kW/m}^2 = 100 \text{ mW/cm}^2$
- Solar cell efficiency
 - Organic : 8-10%
 - perovskites: 20%
 - Silicon : 12-18%
 - Research: 40%
- Harvesting
 - 1 - 10 mW/cm^2 sunlight
 - 10 - 100 $\mu\text{W/cm}^2$ indoors
- Maximum Power Point ?

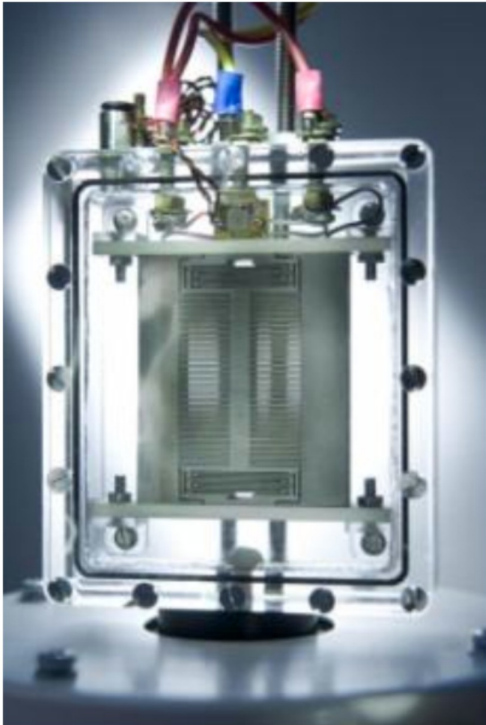
Solar Cell I-V Curve in Varying Sunlight



By ZyMOS - ZyMOS, CC BY-SA 3.0, <https://commons.wikimedia.org/w/index.php?curid=1352608>



Vibration energy harvestings



| Piezoelectric converters | Electromagnetic converters | Electrostatic converters |
|--------------------------------|----------------------------|---------------------------------------|
| Use of piezoelectric materials | Use of Lenz's law | Use of a variable capacitor structure |
| | | |

Table 5. Electret-free electrostatic vibration energy harvesters from the state of the art

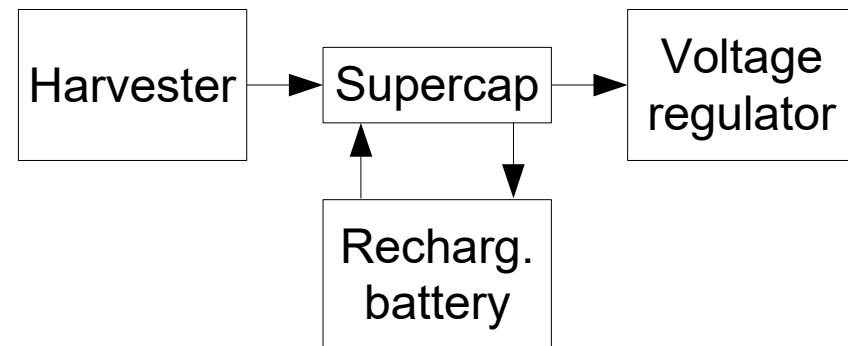
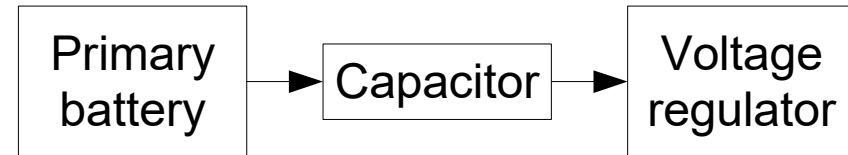
| Author | Ref | Output power | Surface | Volume | Polarization voltage | Vibrations |
|-----------|------|-------------------|----------------------|-----------------------|----------------------|-----------------|
| Tashiro | [19] | 36 μ W | | 15000 mm ³ | 45V | 1,2G@6Hz |
| Roundy | [24] | 11 μ W | 100 mm ² | 100 mm ³ | | 0.23G@100Hz |
| Mitcheson | [25] | 24 μ W | 784 mm ² | 1568 mm ³ | 2300 V | 0.4G@10Hz |
| Yen | [26] | 1,8 μ W | 4356 mm ² | 21780 mm ³ | 6 V | 1560Hz |
| Despesse | [21] | 1050 μ W | 1800 mm ² | 18000 mm ³ | 3 V | 0.3G@50Hz |
| Hoffmann | [23] | 3.5 μ W | 30 mm ² | | 50 V | 13G@1300-1500Hz |
| Basset | [22] | 61nW ¹ | 66 mm ² | 61.49mm ³ | 8 V | 0.25G@250Hz |

S. Boisseau, G. Despesse and B. Ahmed Seddik, Electrostatic Conversion for Vibration Energy Harvesting, Small-Scale Energy Harvesting, Intech, 2012

$$C = \epsilon \cdot S / d ; \quad Q = CV ; \quad dE = V \cdot dQ$$

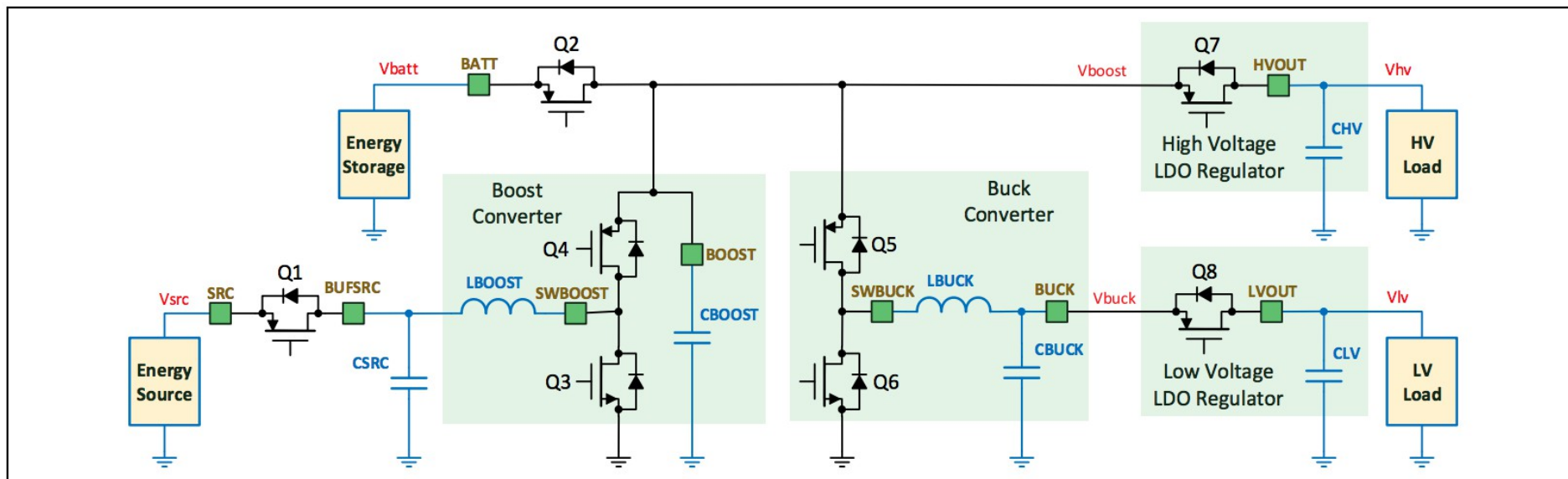
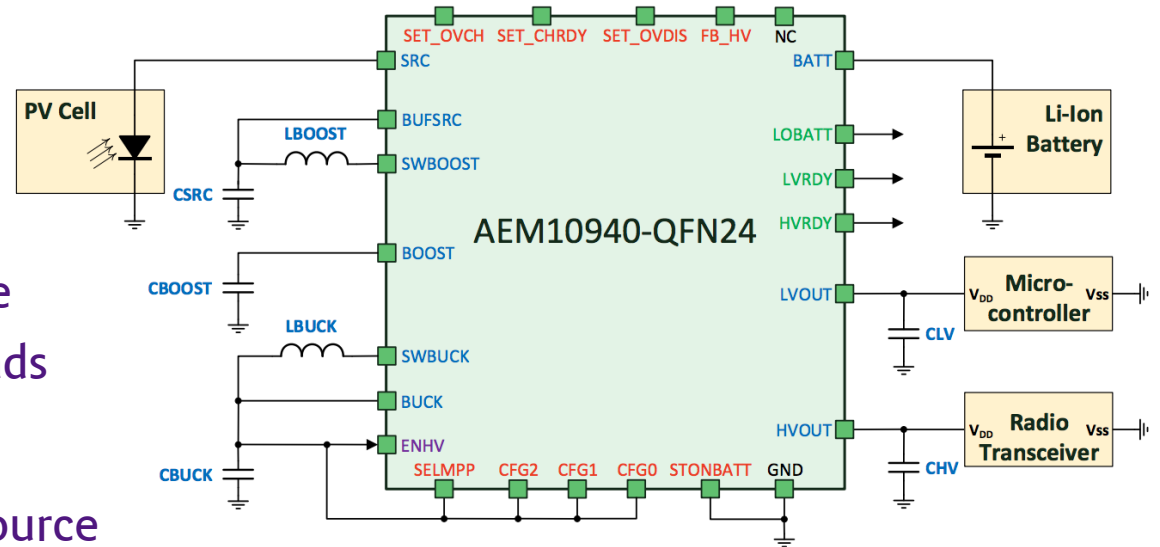
Energy storage for sensor node

- Primary battery
 - Shelf life
 - Limited current
 - voltage drop, aging
 - requires parallel capacitor
 - Temperature
- Temporary storage
 - Rechargeable battery
 - Yield ~ 90%, limited current
 - A few A.h under 3.7 V
 - Supercap
 - high current, 95% yield,
 - a few F capacity

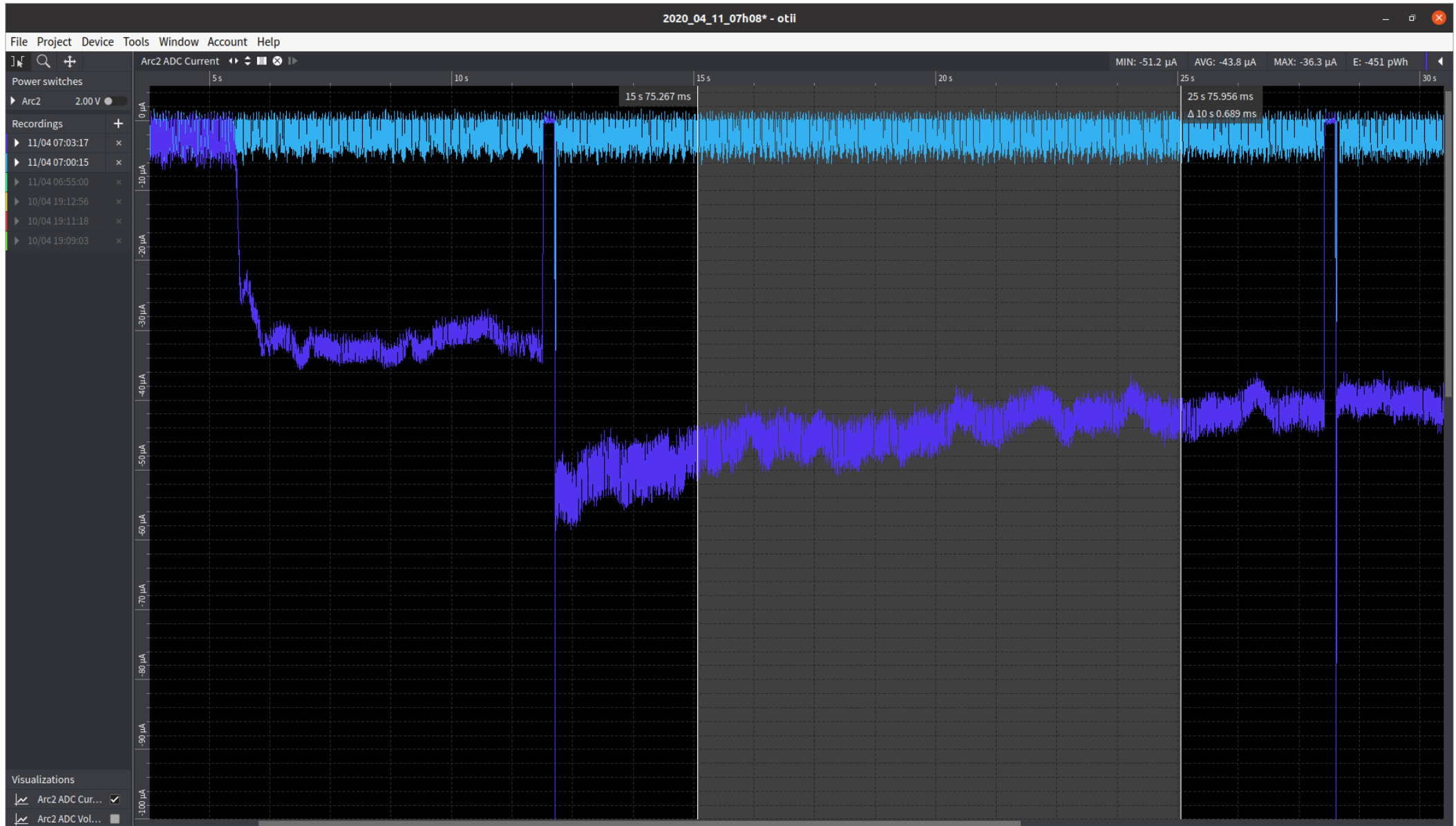
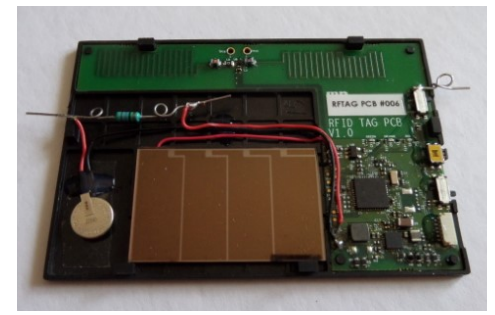


Scavenging electronics

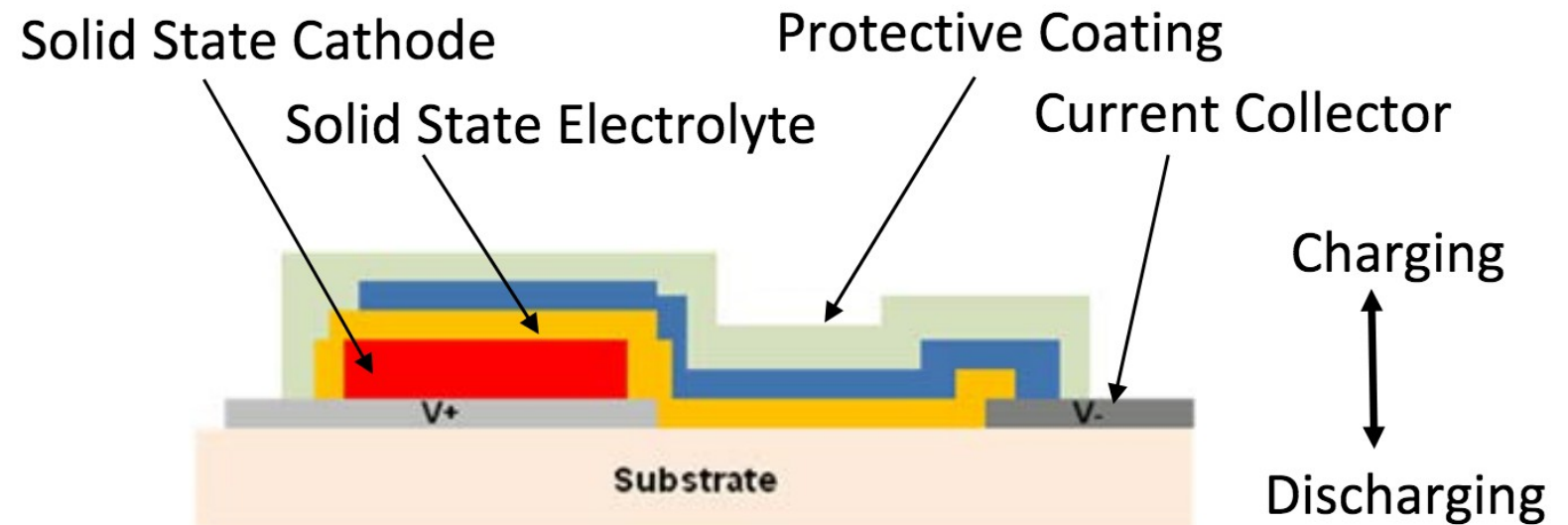
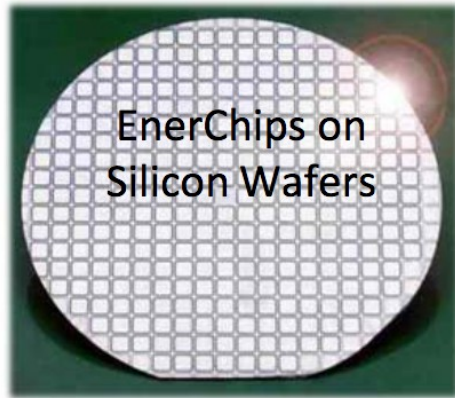
- Goals
 - Deal with variable source voltage, power
 - Control storage charge/discharge
 - Deliver regulated voltages to loads
- Example : AEM10940
 - Cold start at 0.38 V and 11 uW source
 - Sustained operation at 0.1 V source



MPTT operation

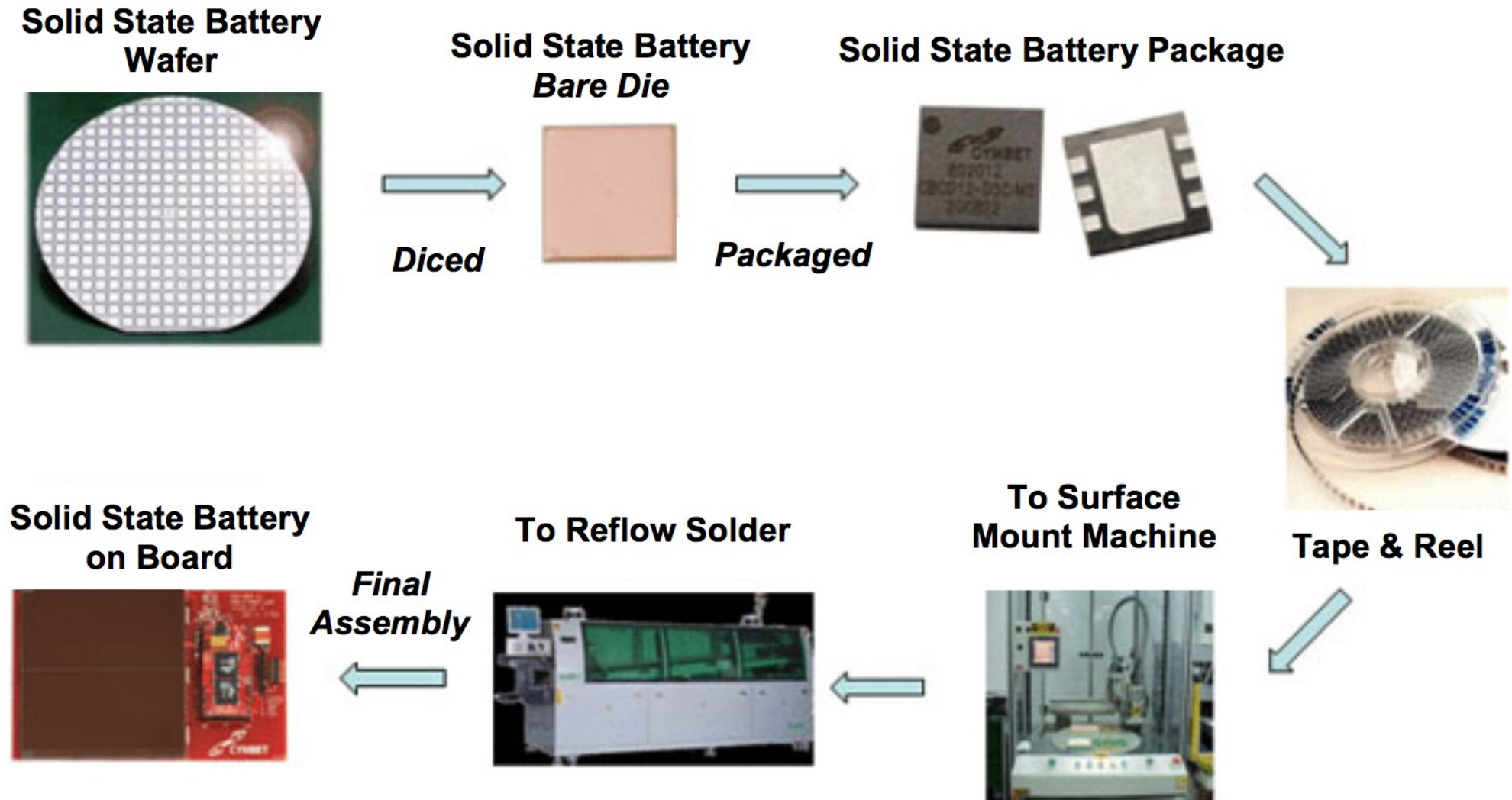


Thin Film Lithium batteries on Silicon



<https://www.cymbet.com/wp-content/uploads/2019/02/Sensors-Expo-2013-Engineering-Ultra-low-power-SoC-sensors.pdf>

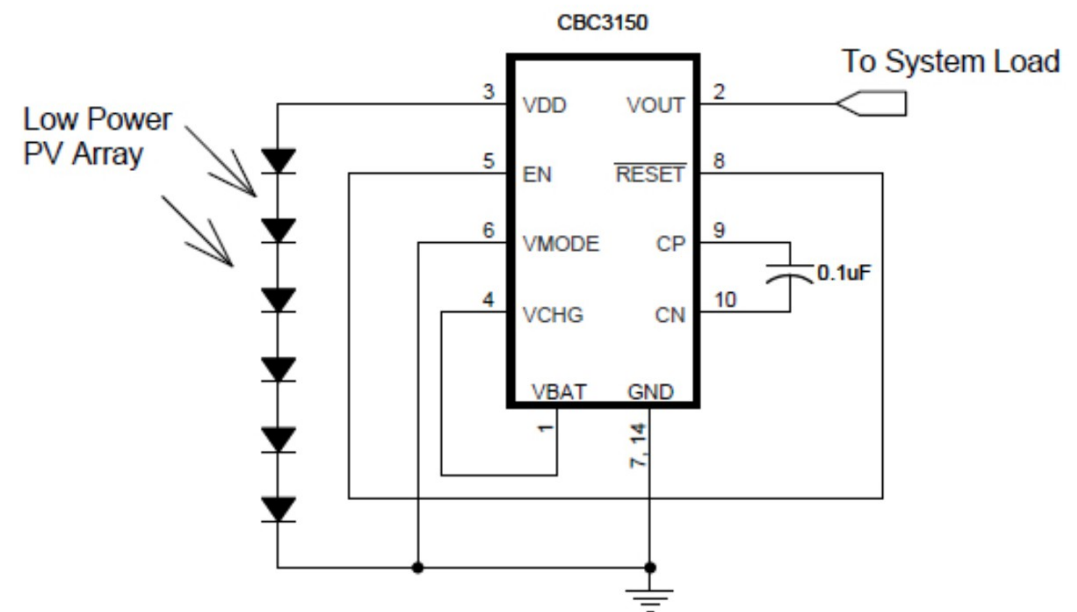
Battery chips used as any other chip



Multiple chips in package



- **CBC3150**
 - 0.2 J, 1 kohm Rint
 - 3.3 V, 10 uA typ output
 - 2.5 – 5.5 V input
 - 9 * 9 mm
 - \$3 (2018)



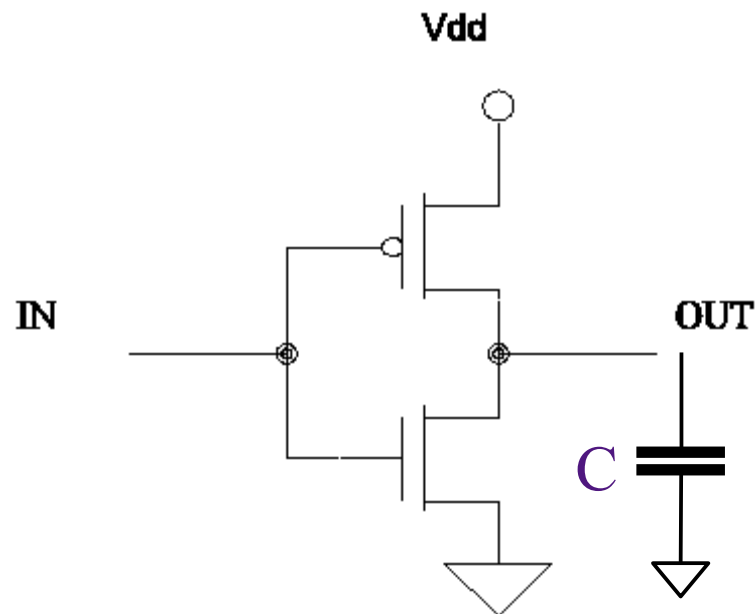
Energy consumption

- Mostly dissipated into heat
 - Except actuation energy, radiation energy
- Static dissipation
 - Analogue (linear) electronics
 - Radio
 - Sensors
 - Energy management
 - Digital electronics (CMOS)
 - Leakage
- Dynamic dissipation
 - Digital electronics (CMOS)
 - Voltage changes on digital signals : $E = \frac{1}{2} C V^2$

Dynamic power consumption

CMOS logic

- Voltage-based logic
 - “1” = 3.3V, “0” = 0V
- Current only needed to fill or drain output capacitance



Energy stored in capacitor

$$dQ = C \cdot dv = i \cdot dt$$

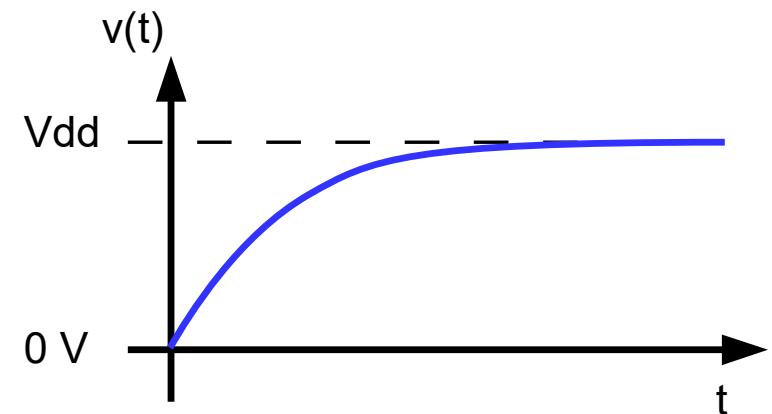
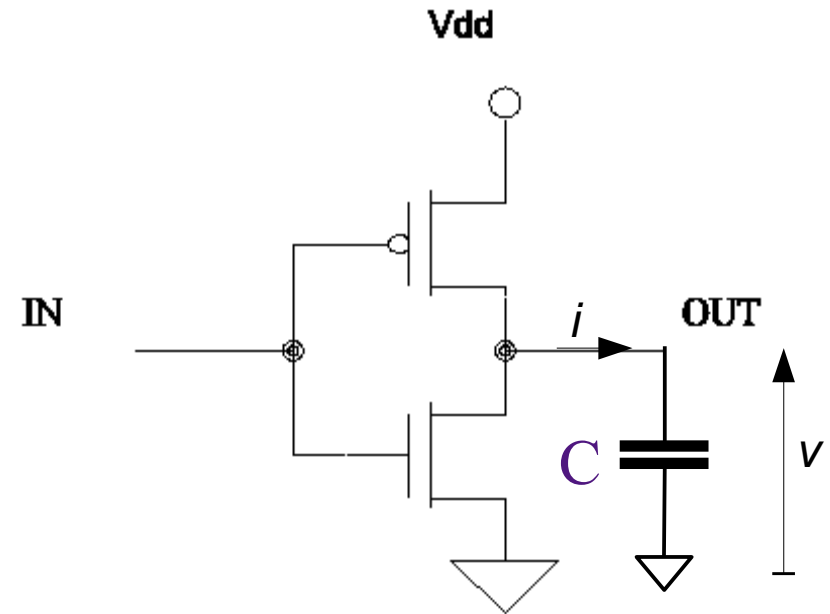
$$i = C \cdot \frac{dv}{dt}$$

$$p_c = v \cdot i = C \cdot v \cdot \frac{dv}{dt}$$

$$E_c = \int_0^{\infty} p_c(t) \cdot dt = C \cdot \int_0^{\infty} v \cdot \frac{dv}{dt} \cdot dt$$

$$= C \cdot \int_0^{Vdd} v \cdot dv = \frac{1}{2} \cdot C \cdot [v^2]_0^{Vdd}$$

$$= \frac{1}{2} \cdot C \cdot Vdd^2$$



Energy supplied by system

$$dQ = C \cdot dv = i \cdot dt$$

$$Q = \int_0^{\infty} i \cdot dt = \int_0^{\infty} C \cdot \frac{dv}{dt} \cdot dt$$

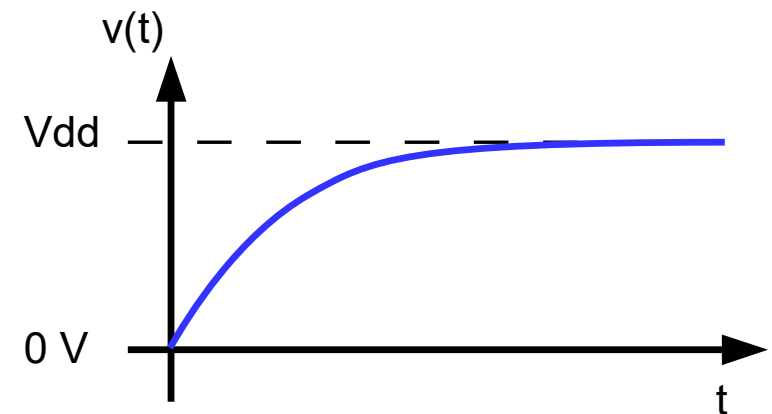
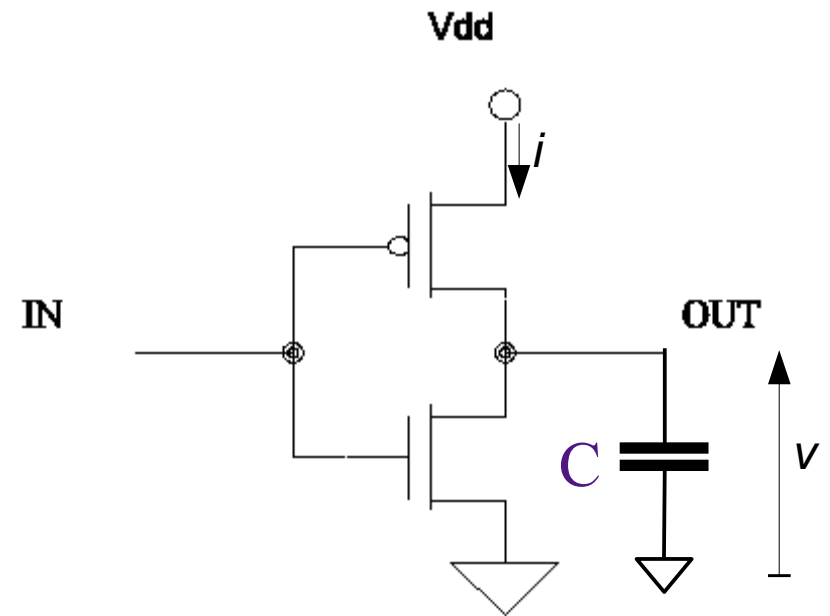
$$= C \cdot \int_0^{Vdd} dv = C \cdot Vdd$$

$$p_s = Vdd \cdot i$$

$$E_s = \int_0^{\infty} p_s(t) \cdot dt = \int_0^{\infty} Vdd \cdot i \cdot dt$$

$$= Vdd \cdot \int_0^{\infty} i \cdot dt$$

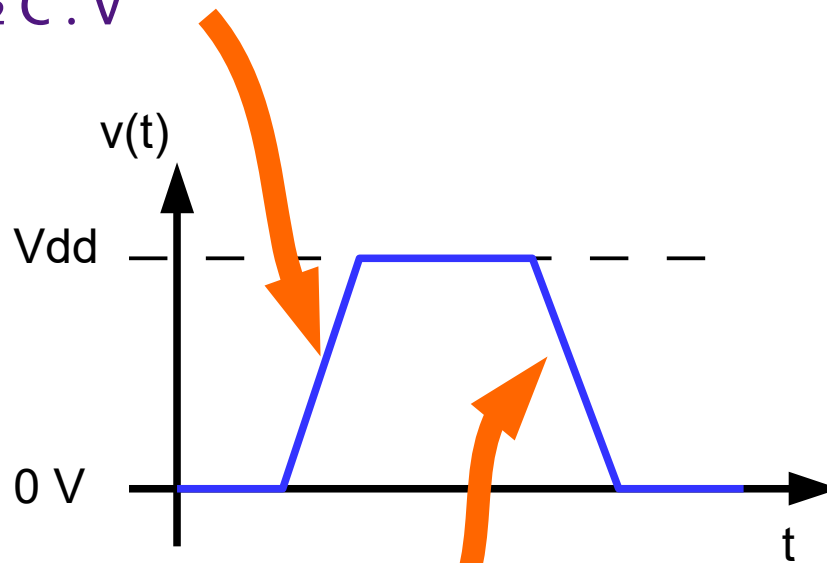
$$= C \cdot Vdd^2$$



Summary

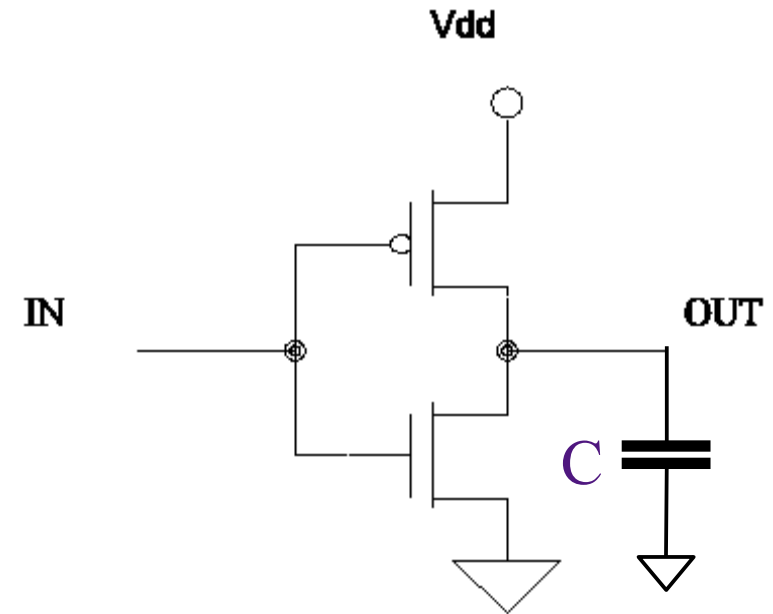
- Energy supplied on rising edge and not stored is dissipated

- $\frac{1}{2} C \cdot V^2$



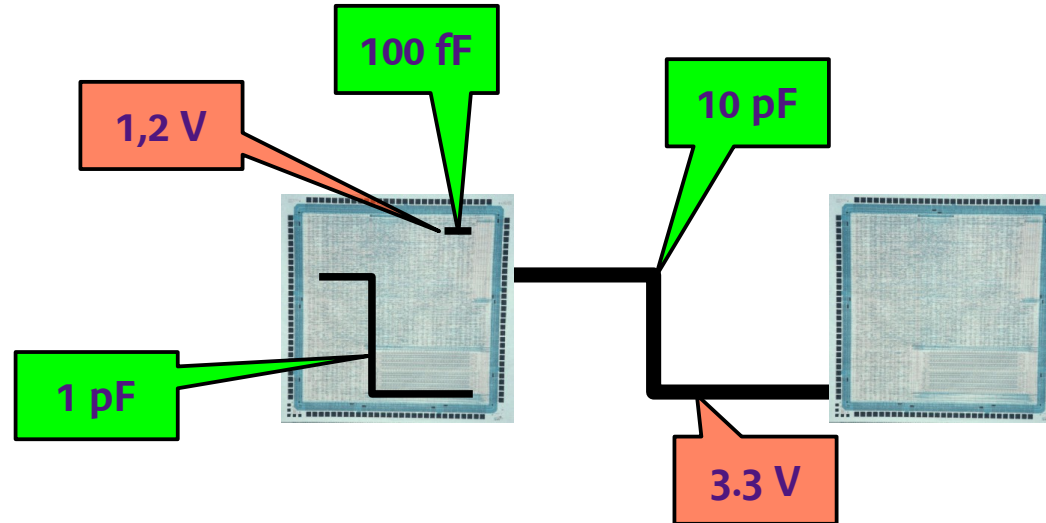
- Stored energy is dissipated on falling edge

- $\frac{1}{2} C \cdot V^2$



Integration, energy benefit

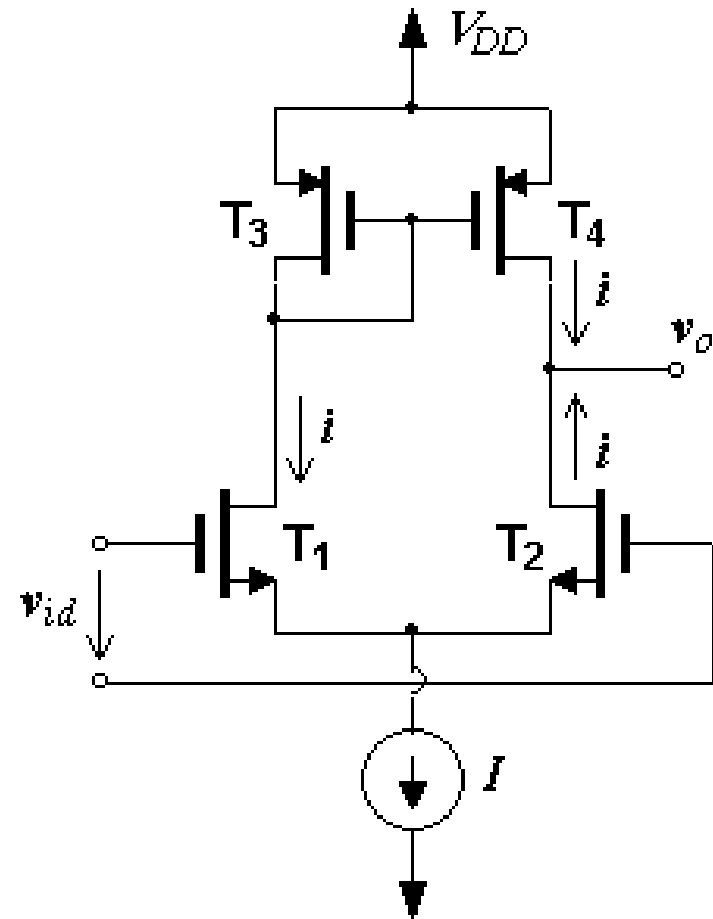
- Dynamic power consumption
 - $E // C V^2$
 - C from 100 fF to 10 pF
 - Standard input-output voltages
 - Lower core voltages



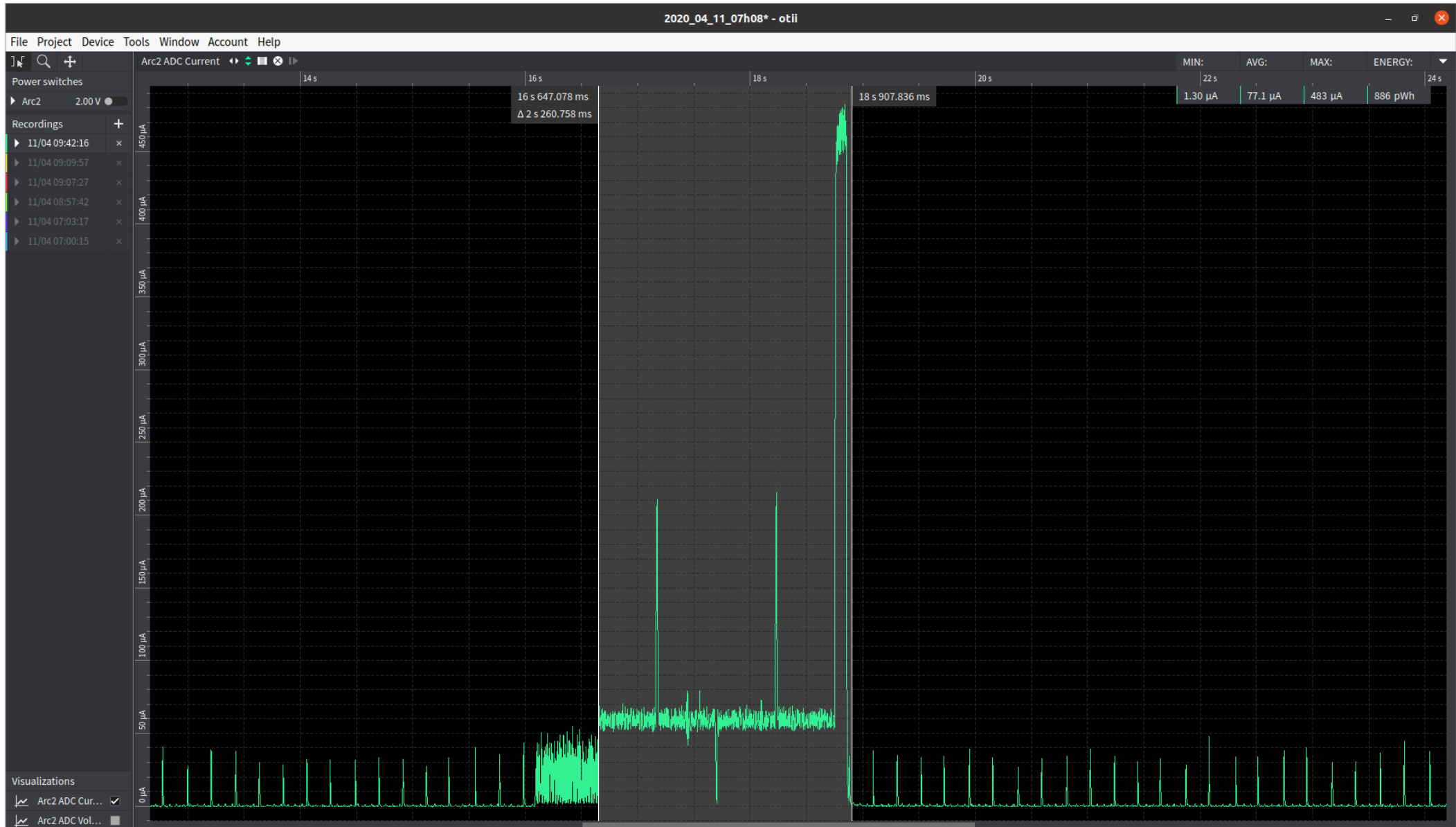
Static power consumption

Steady current flow

- Analogue electronics
 - Current is constant by design
- Digital electronics
 - Leaks at junctions, channels
- Only cure is to turn power off



Typical supply current measurement

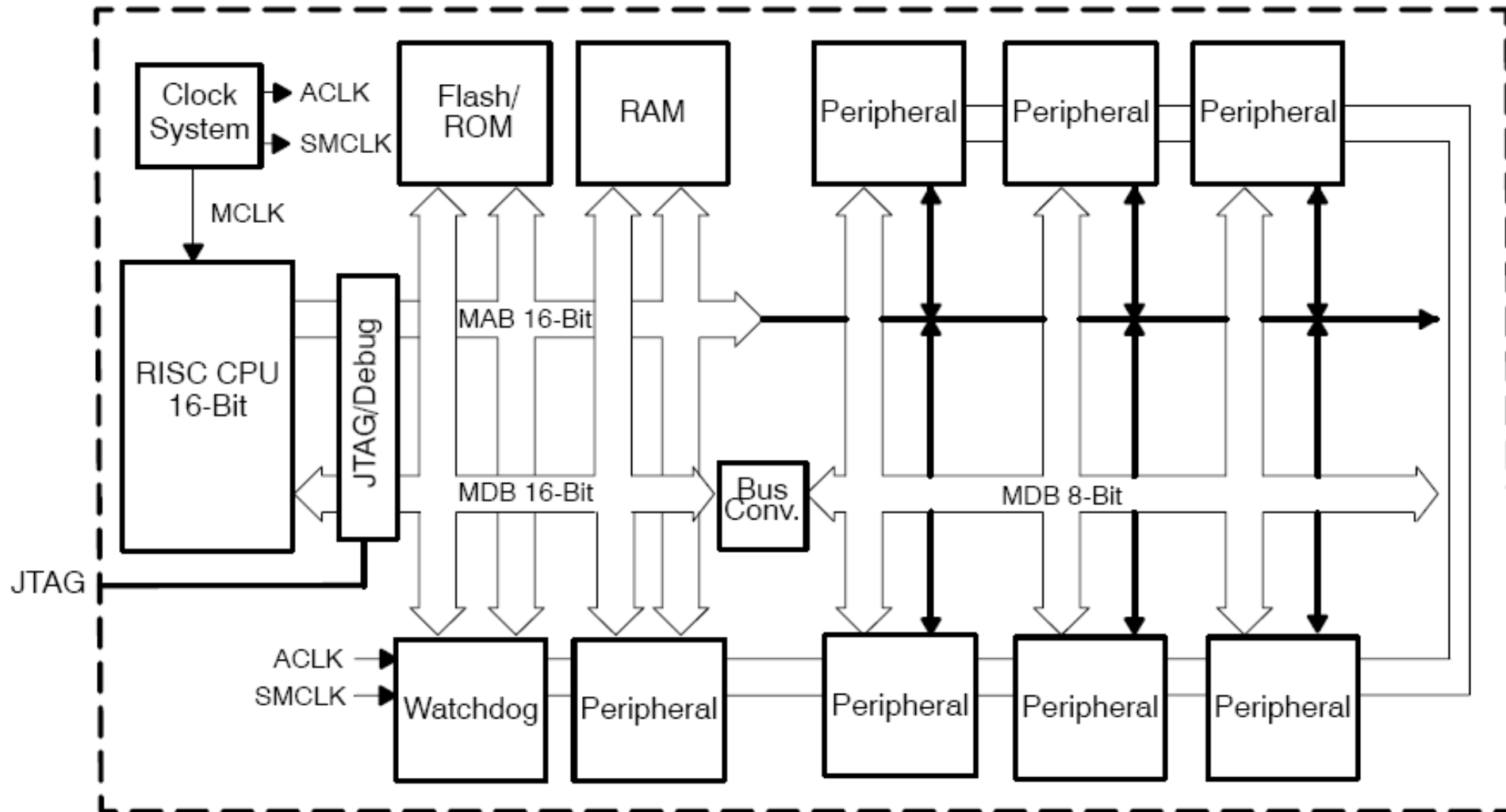


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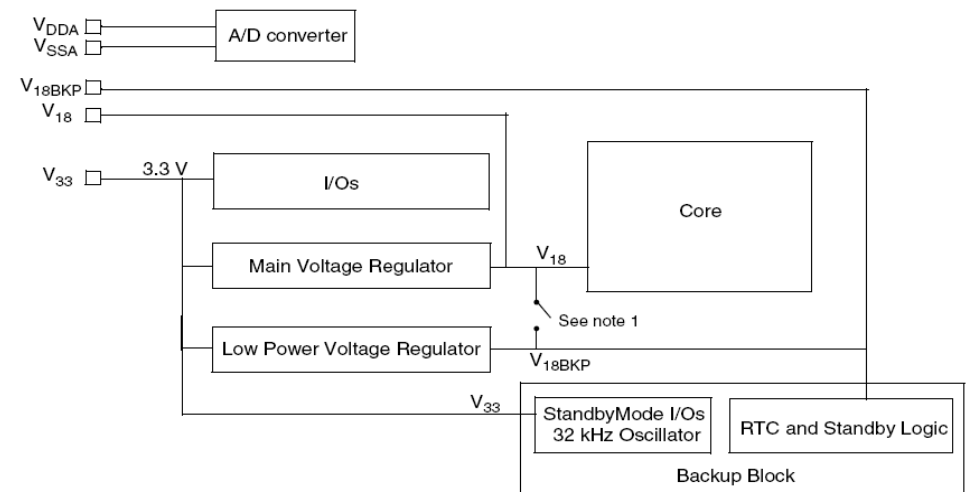
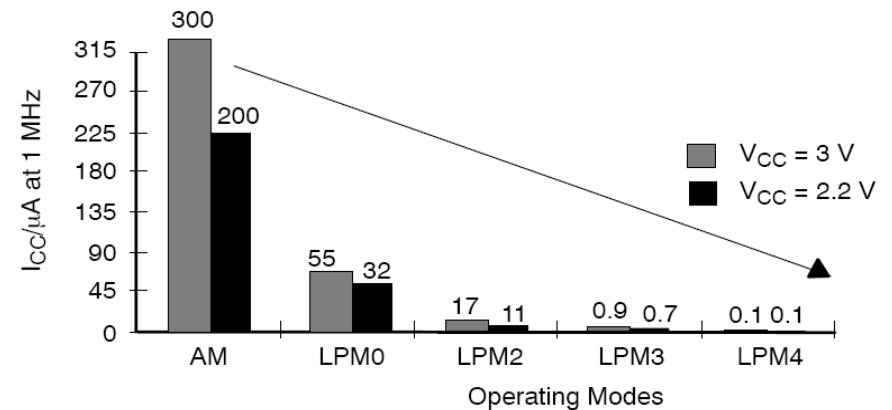
Microcontrollers

Microcontroller typical block diagram

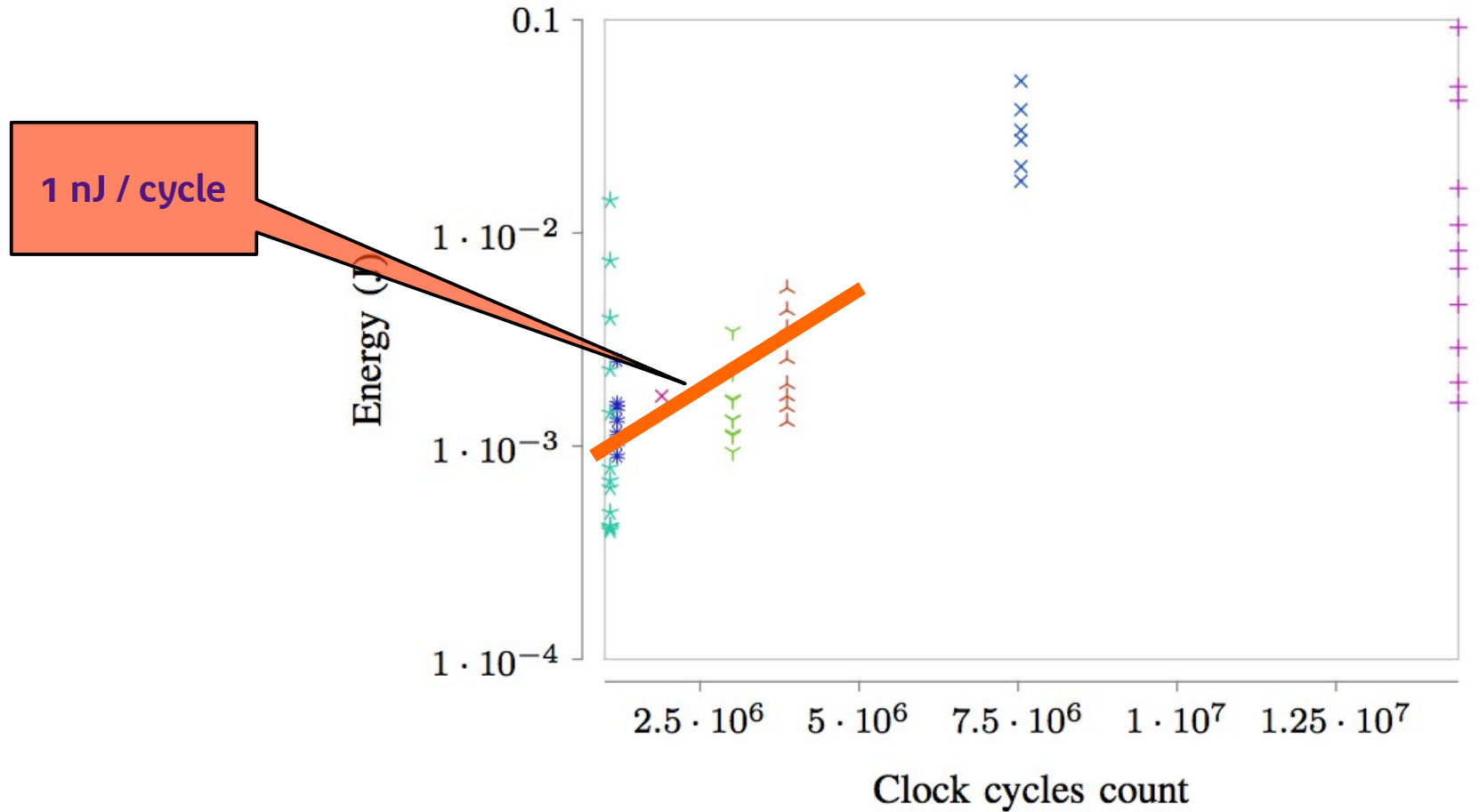


Microcontroller low-power features

- Instruction word size
 - Compact instruction set
 - Native 8 bit (x86, AVR)
 - Compact 16 bit (ARM Thumb, MSP430)
- Selective disabling of functions
 - Clock gating, power gating
 - Low-power vs startup time tradeoff
- Several oscillators
 - Ext. crystal, 32 kHz, internal RC
- Several voltage regulators



Microcontroller energy consumption

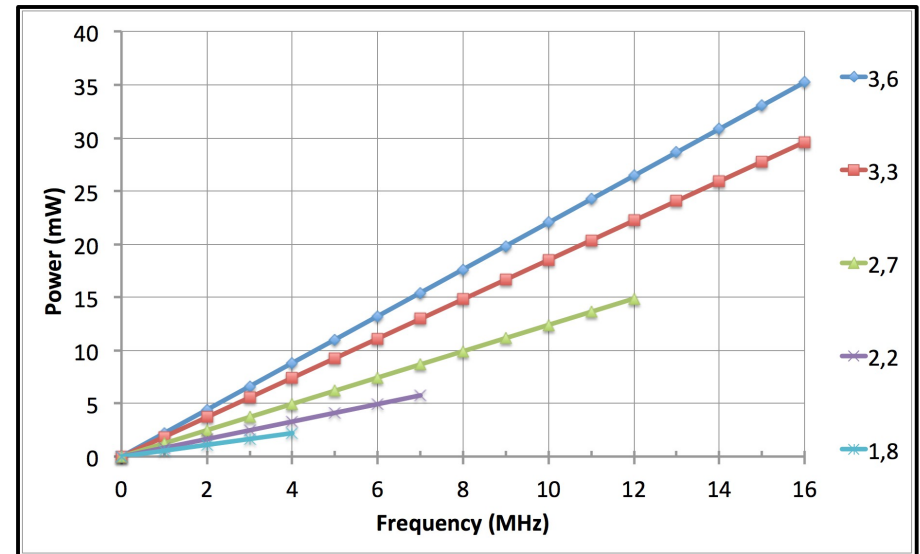


x Z8 Encore! XP ^ C8051 * EFM32 x STM32W
+ PIC y MSP430 * STM32F

I. Tsekoura et al., "An evaluation of energy efficient microcontrollers," 2014 9th International Symposium on Reconfigurable and Communication-Centric Systems-on-Chip (ReCoSoC), Montpellier, 2014, pp. 1-5. doi: 10.1109/ReCoSoC. 2014.6861368

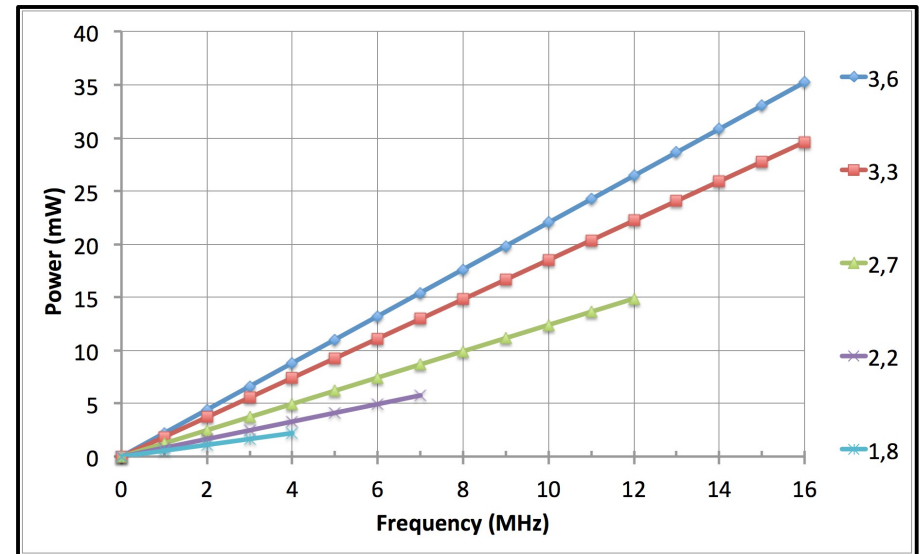
Low power operation

- Dynamic power consumed
 - $P \propto V^2 \cdot f$
- Fixed approach
 - Pick required frequency
 - Pick required voltage
 - Pick voltage regulator
 - Design for worst case
- Variable frequency, fixed voltage
 - On-Off clock?
 - Continuously variable frequency?



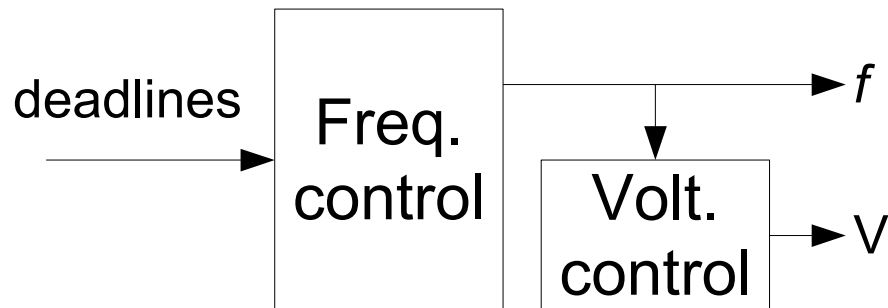
Min energy operation

- Dynamic power consumed
 - $P \propto V^2 f$
- Task Duration = $n \cdot 1/f$
- Energy = $P \cdot \text{Duration}$
 $\propto n V^2$

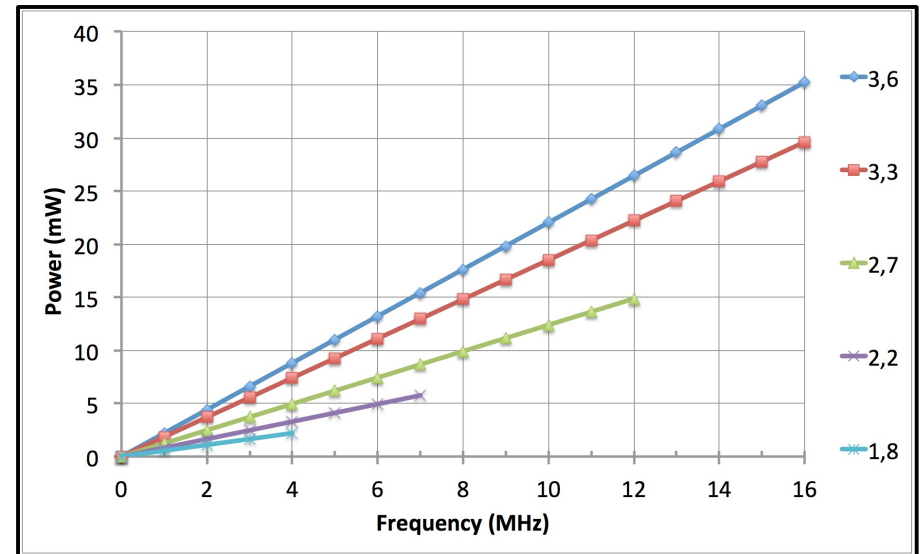


Min energy operation

- Dynamic power consumed
 - $P \propto V^2 \cdot f$
- Task Duration = $n \cdot 1/f$
- Energy = $P \cdot \text{Duration}$
 $\propto n \cdot V^2$
- Operate as slowly as possible
- Control voltage accordingly

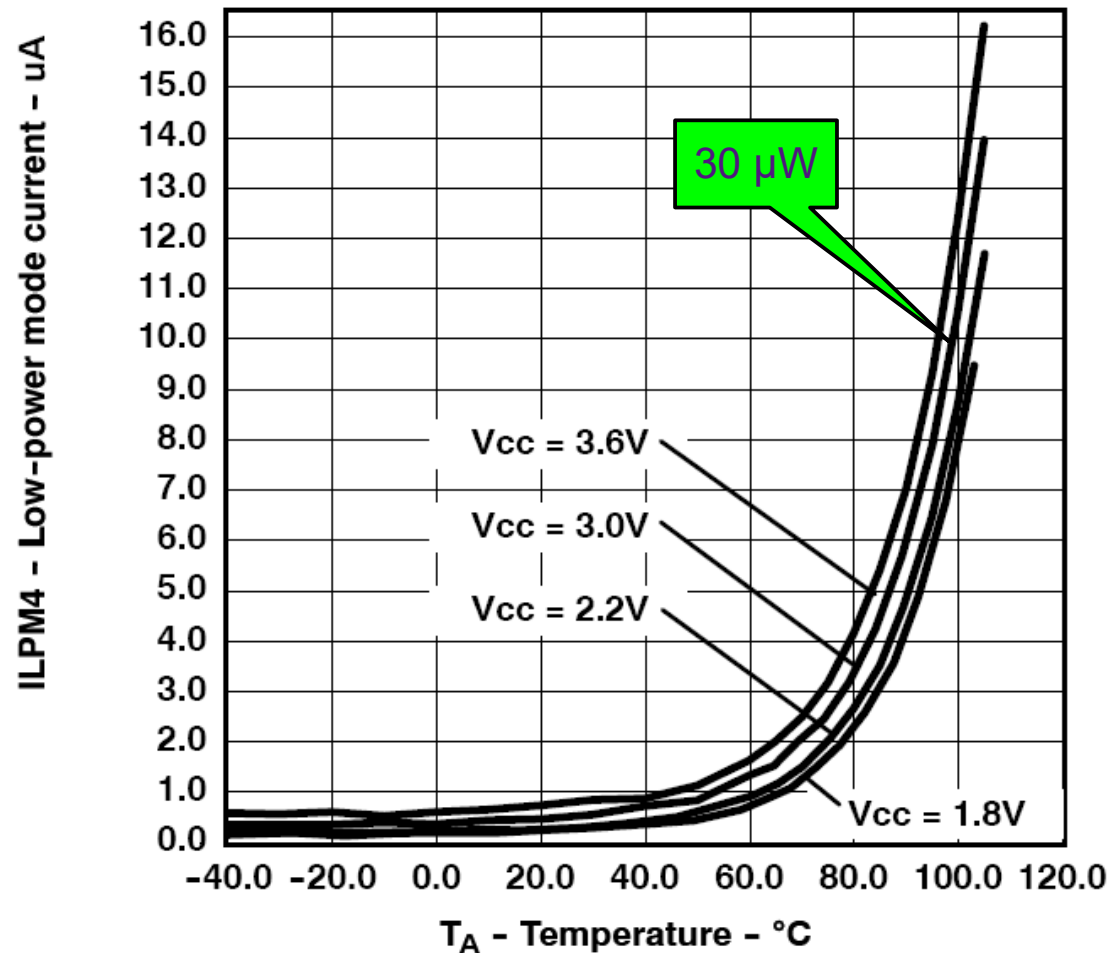


- Leakage/steady current not accounted for



Microcontroller leakage current

- In standby mode, just a giant diode
- Don't buy more memory than you really need



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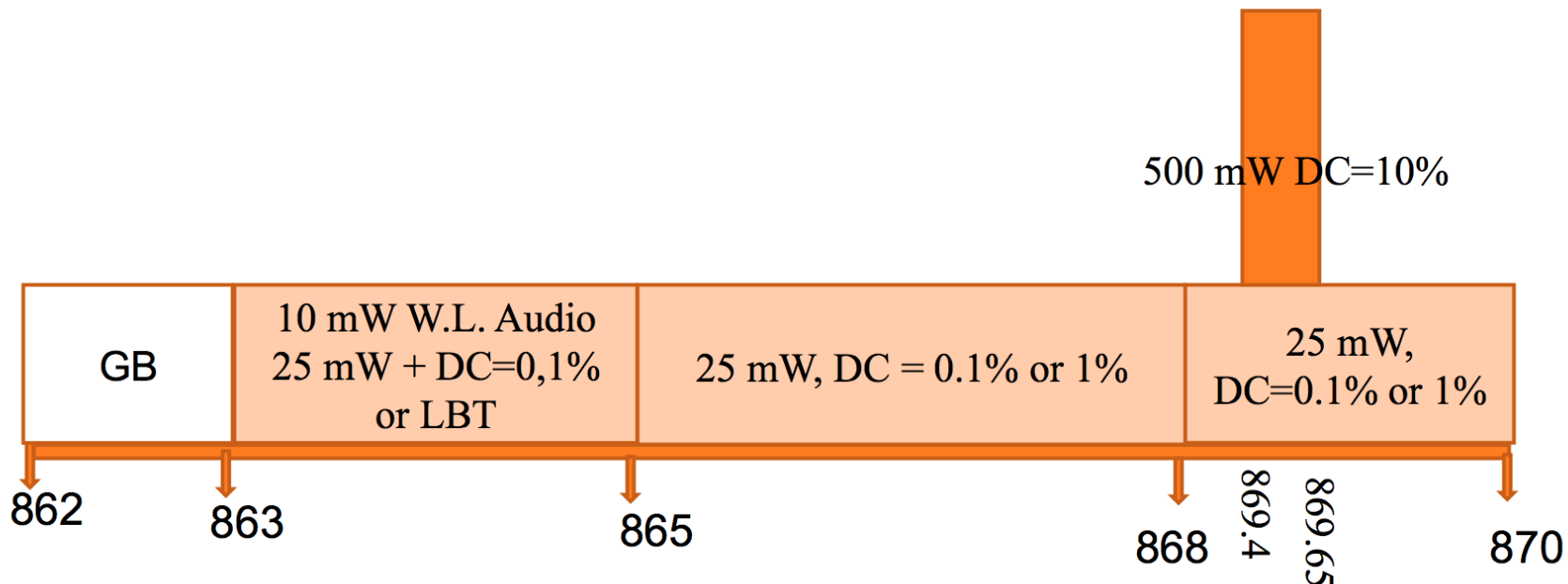
Spectrum, PHY layer and radio chips

Licensed-exempt spectrum

Licensed-exempt spectrum

License-exempt, but still regulated

- Maximum power, power density
- Duty cycle
- Usage
- E.g. DECT 1.9 GHz band, only to be used for DECT
- E.g., 862-870 MHz unlicensed band (CEPT ERC Rec 70-03)

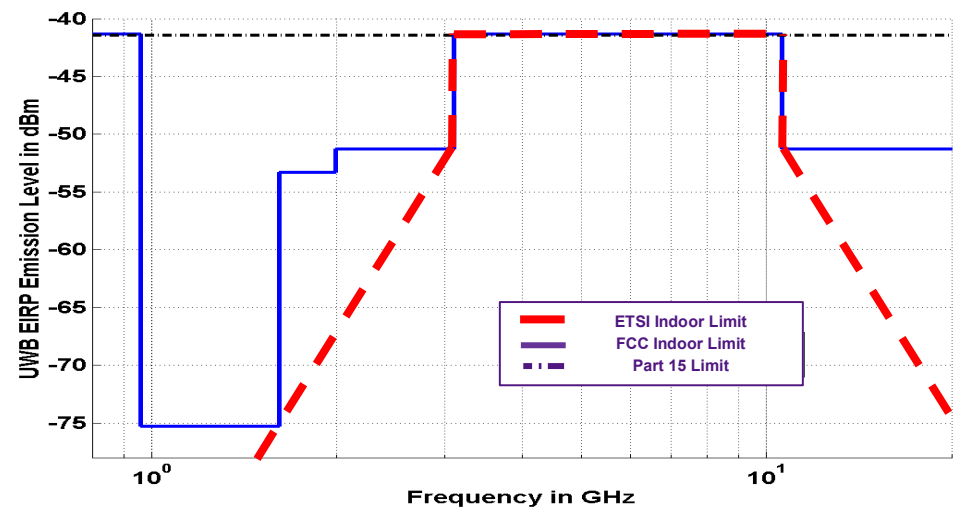


Unlicensed frequency bands (1/2)

- 2.4 GHz ISM band
 - 2.400-2.4835 GHz world-wide, 4W EIRP maximum
 - Microwave ovens, 802.11 (WiFi), 802.15.4, Bluetooth, prop. radios
 - fairly polluted
 - line of sight propagation
 - short antennas
- UHF 900 MHz band
 - continent specific : 868 MHz Europe, 902-928 MHz USA, 915 Japan
 - W-MBus, Zwave, LoRa, SigFox, prop. radios
- UHF 400 MHz band
 - continent specific, 433 MHz in Europe
- VHF 169 MHz band
 - better indoor penetration, long antennas

Unlicensed frequency bands (2/2)

- 5 GHz UNII band
 - IEEE 802.11a
 - silicon-only transceiver less efficient
- 60 GHz
 - Very short transmission range
 - Silicon transceiver still to be designed
- Ultra-Wide Band
 - legal since 2003 in the USA
 - 3.1 – 10.6 GHz
 - -41,3 dBm/MHz max avg
 - 0 dBm/50 MHz max peak
 - good opportunity for positioning
 - opportunity for new radio design



Licensed spectrum

Telecom operator cellular IoT systems

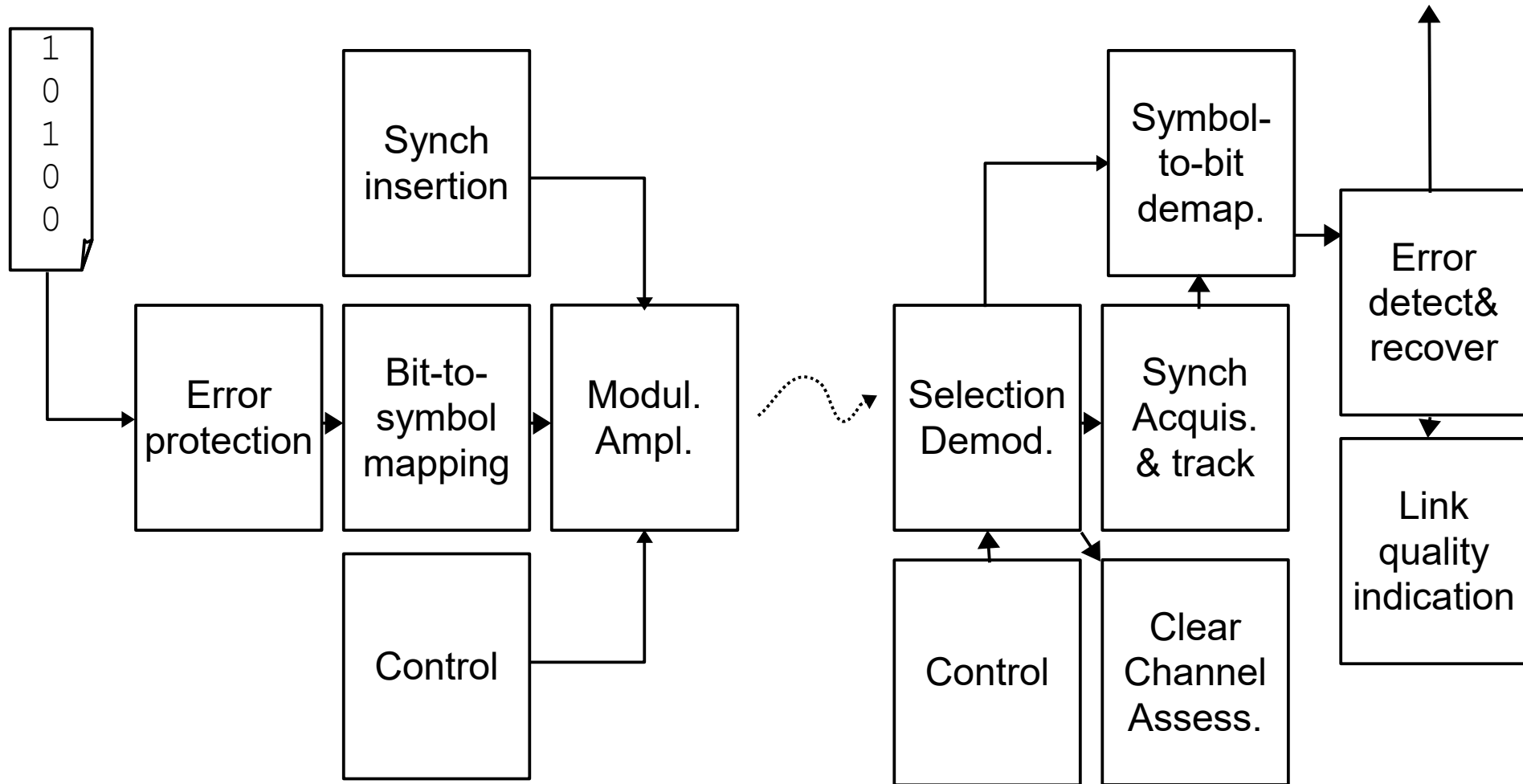
- 3GPP Release-13 (June 2016)
 - 10-20 dB coverage extension, reduced UE complexity/cost
 - 10 years on 5 W.h battery (Power Saving Modes, extended DRX)
- EC-GSM (2G improvement)
 - Extended-coverage through blind repetition
 - Base station and UE software upgrade
 - 350 bps – 240 kbps, 200 kHz bandwidth
- LTE-M (4G improvement)
 - 10 kbps – 1 Mbps, 1.08 MHz bandwidth
- NB-IoT (new radio for 4G)
 - Narrowband (180 kHz bandwidth), 20 kbps – 250 kbps
 - 3 modes of operation : LTE in-band, LTE guard band or standalone
- 5G
 - Will use LTE-M and NB-IoT, NR-Lite radio for Rel 17 (2022)

Telecom operator bands (3GPP)

- 2G (EC-GSM)
 - 900 MHz, 1800 MHz
- 4G (NB-IoT, LTE-M)
 - 850 MHz, 2.6 GHz
- 5G
 - 700 MHz, 3.6 GHz, 26 GHz

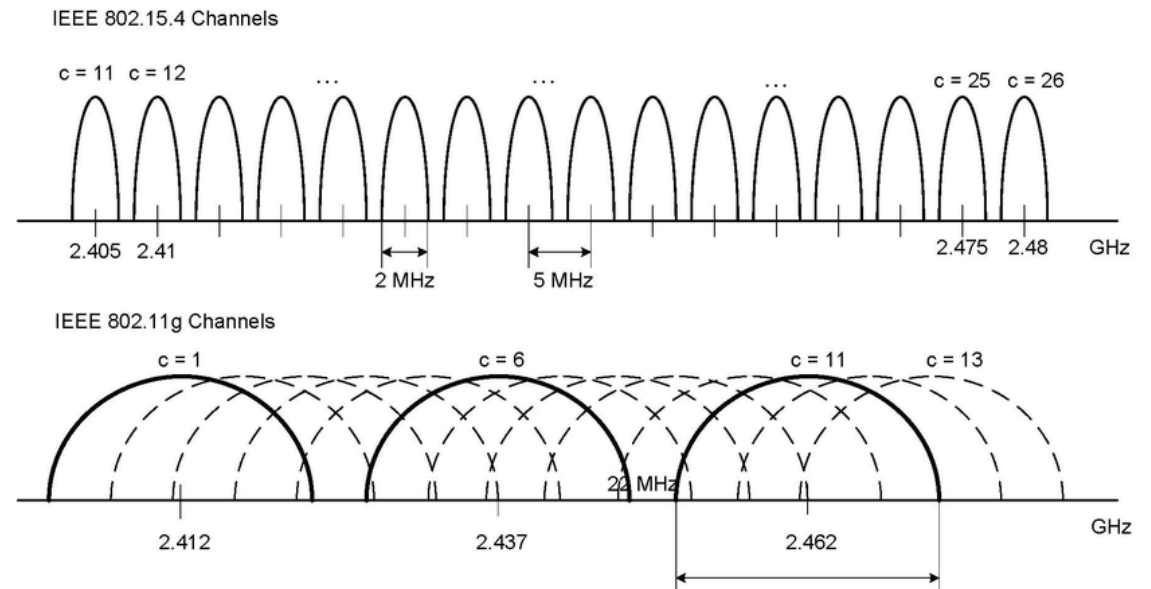
PHY layer

PHY layer block diagram



WPAN: IEEE 802.15.4 -2003 PHY

- 900 MHz and 2.4 GHz bands
 - 16 channels in 2.4 – 2.4835 GHz, 5 MHz spacing, 250 kbps
 - O-QPSK 2Mcps DSSS
- sensitivity
 - 2.4 GHz : better than -85 dBm at 1% PER
- at least -3 dBm output power
 - about 30 m range
- turn around-time
 - 12 symbol periods
- used in Zigbee, W-HART, ISA100



Long Range Wide Area Low Power PHY

- **Sigfox**

- 868 MHz band, 100 Hz channel, 100 bps, BPSK, 25 mW
- All-proprietary system, originally unidirectional
- <https://build.sigfox.com/sigfox-device-radio-specifications>
- Single world-wide network
- Simple IoT device, complexity in the network
-

- **LoRa**

- 868 MHz, 125 kHz channel, chirps, 300bps-5kbps, dynamic adaptation
- LoRa Alliance www.lora-alliance.org
 - LoRaWAN 1.1 spec public, does not describe PHY layer
- Semtech still sole chip vendor

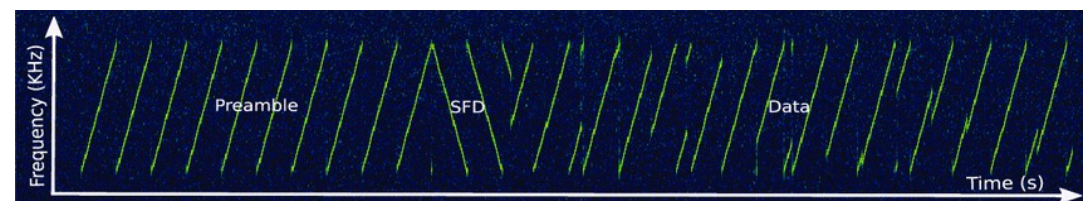


Figure on ResearchGate.

https://www.researchgate.net/figure/A-snapshot-of-LoRa-transmission-that-shows-up-down-and-data-chirps-as-seen-on_fig1_331294324

Practical implementation

Typical radio transceiver architecture

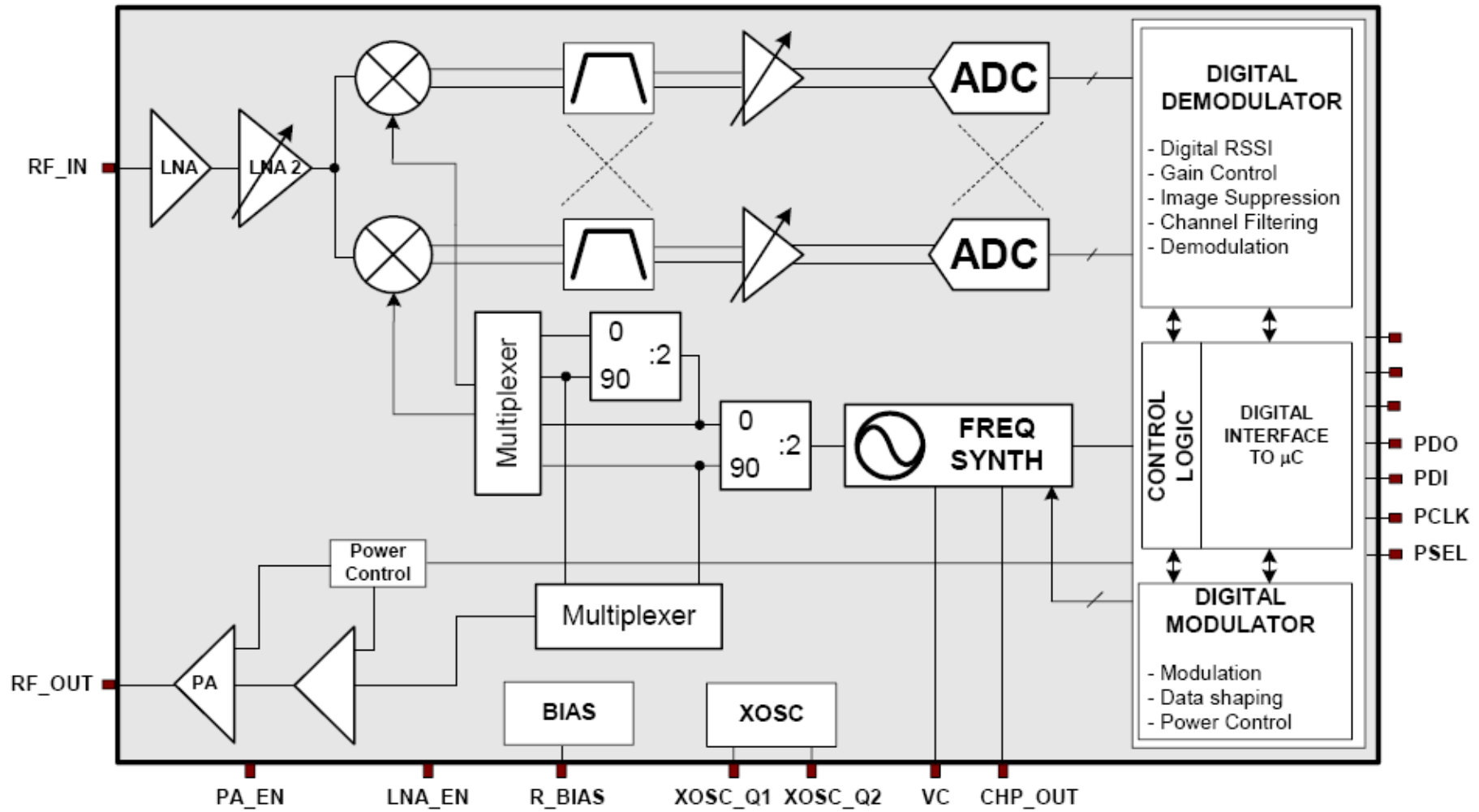
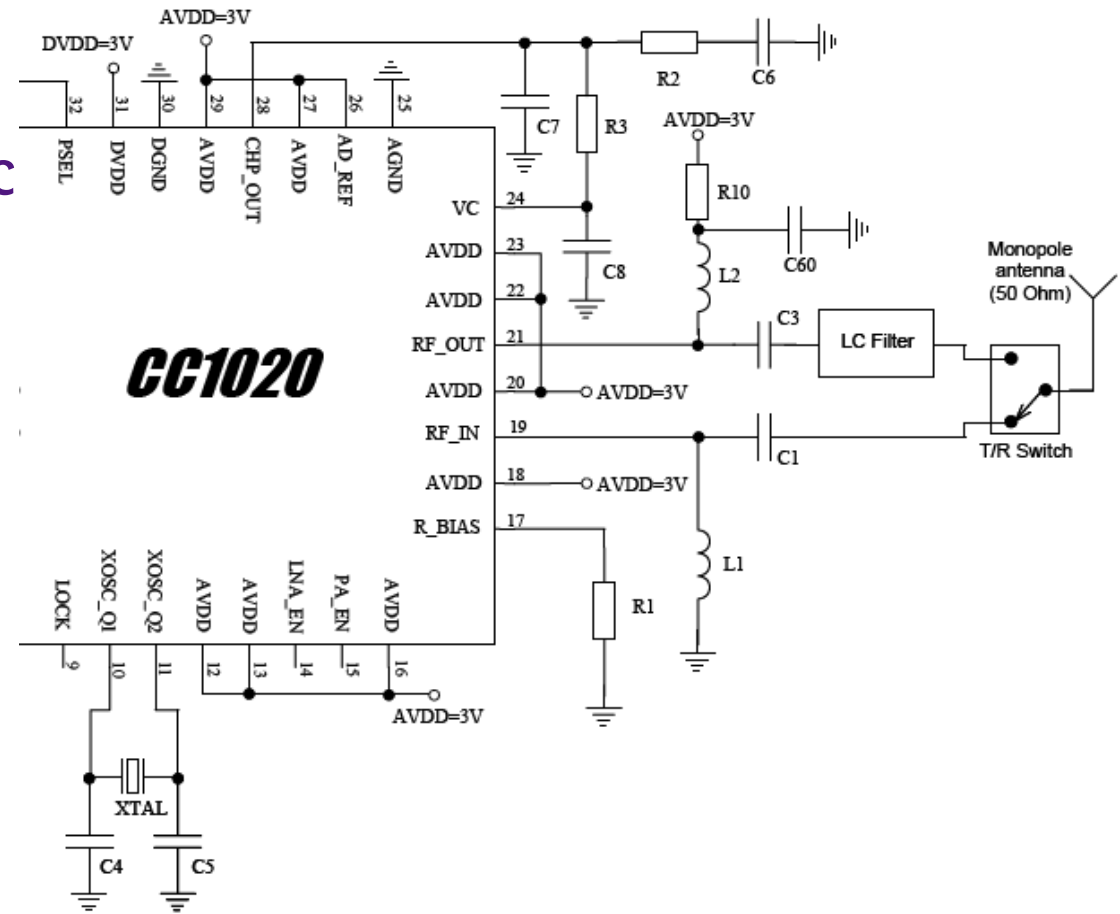


Figure 2. *CC1020* simplified block diagram

Radio transceiver in analogue world

- 5€ radio chip
- Minimal external electronic components
- Antenna implementation
 - PCB tracks : free, fair perf
 - Discrete : 0.5€, good perf
- Resonator
 - Quartz crystal : 0.5€
 - Temperature compensation

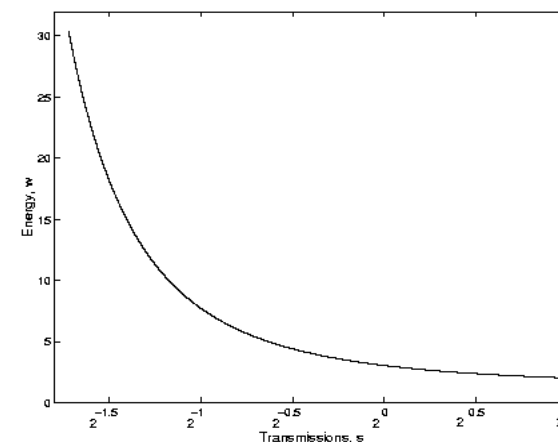


Energy optimizations at PHY layer

- **Semiconductor technology**
 - well-known Moore's law does not really apply to analogue or RF electronics
 - bias current pretty much constant
 - voltage can't go below a few V_t
- **Frequency band**
 - Higher operating frequencies require more bias current in linear circuits
- **Receive sensitivity**
 - lower gain can do with lower bias current in linear circuits
 - bypass some filtering stages
 - low-performance wake-up receiver (totally passive?)
- **Short wake-up, carrier sensing, sync and turn-around time**
 - spend less time in un-productive states

Other ideas for PHY layer

- Transmit power control
 - transmit at minimal power required for correct decoding
 - reduces interference to other nodes
 - power saving is marginal below 0dBm
- Transmit speed
 - Shannon's law $C = B \log_2 (1+S/N)$ suggests that less energy is required for slow transmission
 - just in time transmission^[1]
 - but (real) receivers will have to stay on longer
- Brand new architectures
 - Non-standard electronics (weak inversion CMOS)
 - MEMS/NEMS passive receivers
 - Impulse-based UWB radios (cf. infra)



[1]. B. Prabhakar, E. Uysal, A. El Gamal, "Energy-efficient transmission over a wireless link via lazy packet scheduling," *Proc. of the IEEE INFOCOM*, Anchorage, 2001

Radio chips

Transceivers gallery

- IEEE 802.11 (WiFi)
- Sub-GHz narrowband
 - TI/ChipCon CC1020
 - TI CC1200
- IEEE 802.15.4-2003
 - Freescale MC13192
 - TI CC2538 (SoC)
- Research directions

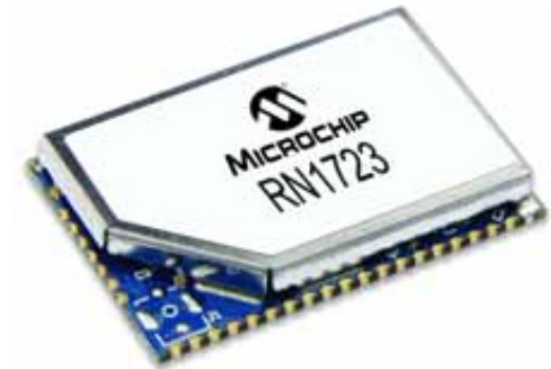
IEEE 802.11 (WiFi) radios

- 802.11b
 - 2.4 GHz, DSSS, 1-11 Mbps
- 802.11a,g
 - 5 GHz, 2.4 GHz, OFDM, 54 Mbps
- typical power consumption^[1]

| Chipset | Sleep (mW) | Idle (mW) | Receive (mW) | Transmit (mW) |
|------------------|------------|-----------|--------------|---------------|
| ORiNOCO PC Gold | 60 | 805 | 950 | 1400 |
| Cisco AIR-PCM350 | 45 | 1080 | 1300 | 1875 |

@ 11 Mbps

- i.e. 150 nJ/bit transmitted, 90 nJ/bit received
- Microchip RN1723 802.11b,g (2016)
 - 40 mA Rx, 120 mA Tx @ 0dBm (190mA @+12dBm), 3.3V
 - 2-10 nJ/bit received



[1] Shih et al, "Reducing Energy Consumption of Wireless, Mobile Devices Using a Secondary Low-Power Channel". MIT RR March 03

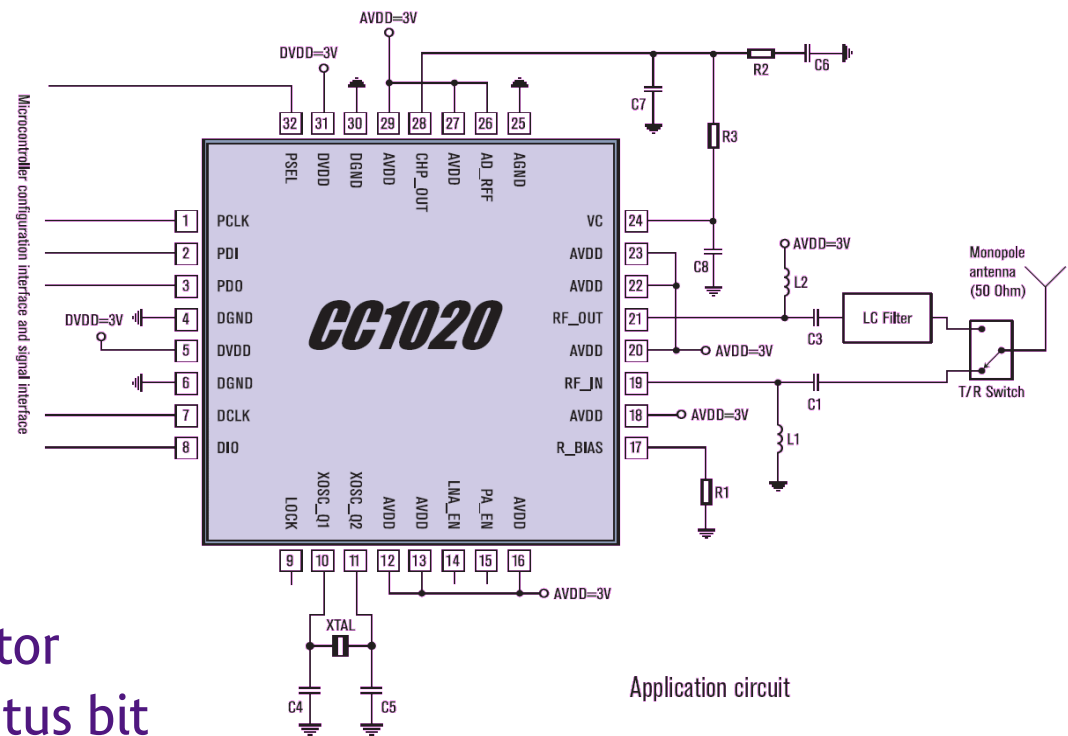
CC 1020

- Monolithic narrowband UHF transceiver

- dual-band 400 and 900 MHz
- FSK/GSK and ASK/OOK
- -20 +10 dBm output power
- 0.45 -153 kbps
- 12.5 – 500 kHz channels

- Digital RSSI

- Received Signal Strength Indicator
- Carrier Sense threshold and status bit



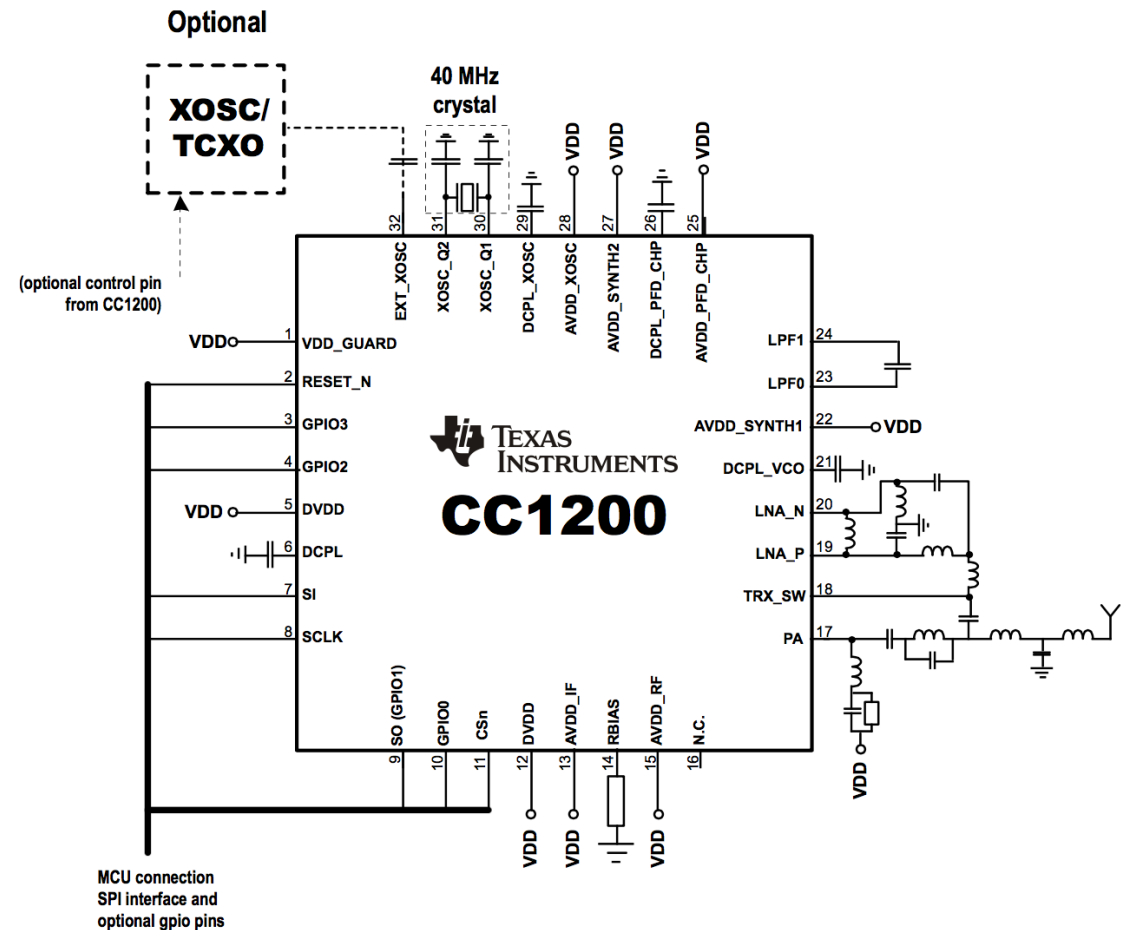
CC1020

| Current Consumption | | | | | |
|---|--|-----------|-----|---------------|--|
| Power Down mode | | 0.2 | 1.8 | μA | Oscillator core off |
| Current Consumption, receive mode 434/868 MHz | | 17.3/17.9 | | mA | |
| Current Consumption, transmit mode 434/868 MHz: | | | | | The output power is delivered to a 50 Ω single-ended load, see also page52. |
| P = -20 dBm | | 10.3/13.7 | | mA | |
| P = -5 dBm | | 12.1/18.1 | | mA | |
| P = 0 dBm | | 13.7/21.9 | | mA | |
| P = 5 dBm | | 16.8/33 | | mA | |
| P = 10 dBm (434 MHz only) | | 23.7 | | mA | |
| Current Consumption, crystal oscillator | | 77 | | μA | 14.7456 MHz, 16 pF load crystal |
| Current Consumption, crystal oscillator and bias | | 500 | | μA | 14.7456 MHz, 16 pF load crystal |
| Current Consumption, crystal oscillator, bias and synthesizer | | 11.5 | | mA | 14.7456 MHz, 16 pF load crystal |

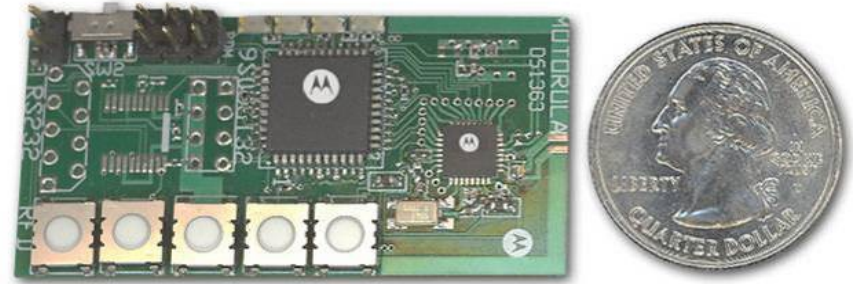
350nJ/bit rec.

CC 1200 (2013)

- Monolithic narrowband VHF/UHF transceiver
 - 169, 400 and 868/900 MHz
 - FSK/GSK/MSK/OOK
 - +16 dBm output power
 - Tx 46mA @+14dBm
 - Rx 19-23 mA
 - 2.0 – 3.6 V supply
- 40 kHz RC int. oscillator
- WakeOnRadio
- AES128 accelerator
- Auto-ACK



Freescal MC13192



- IEEE 802.15.4 2003 compliant
 - -30 dBm (min) to 0 dBm (typ) output power, (+3.6 dBm) max
 - transmit 34 mA @ 0dBm (under 2.7 V)
 - receive 37 mA (under 2.7V)
 - several power-down modes 1-500 μ A
- 7 external components
- On-chip voltage regulator
- Some MAC support on-chip
 - timers
 - automatic ACKnowledge hardware generator

400nJ/bit rec.



MC13192 states and power consumption

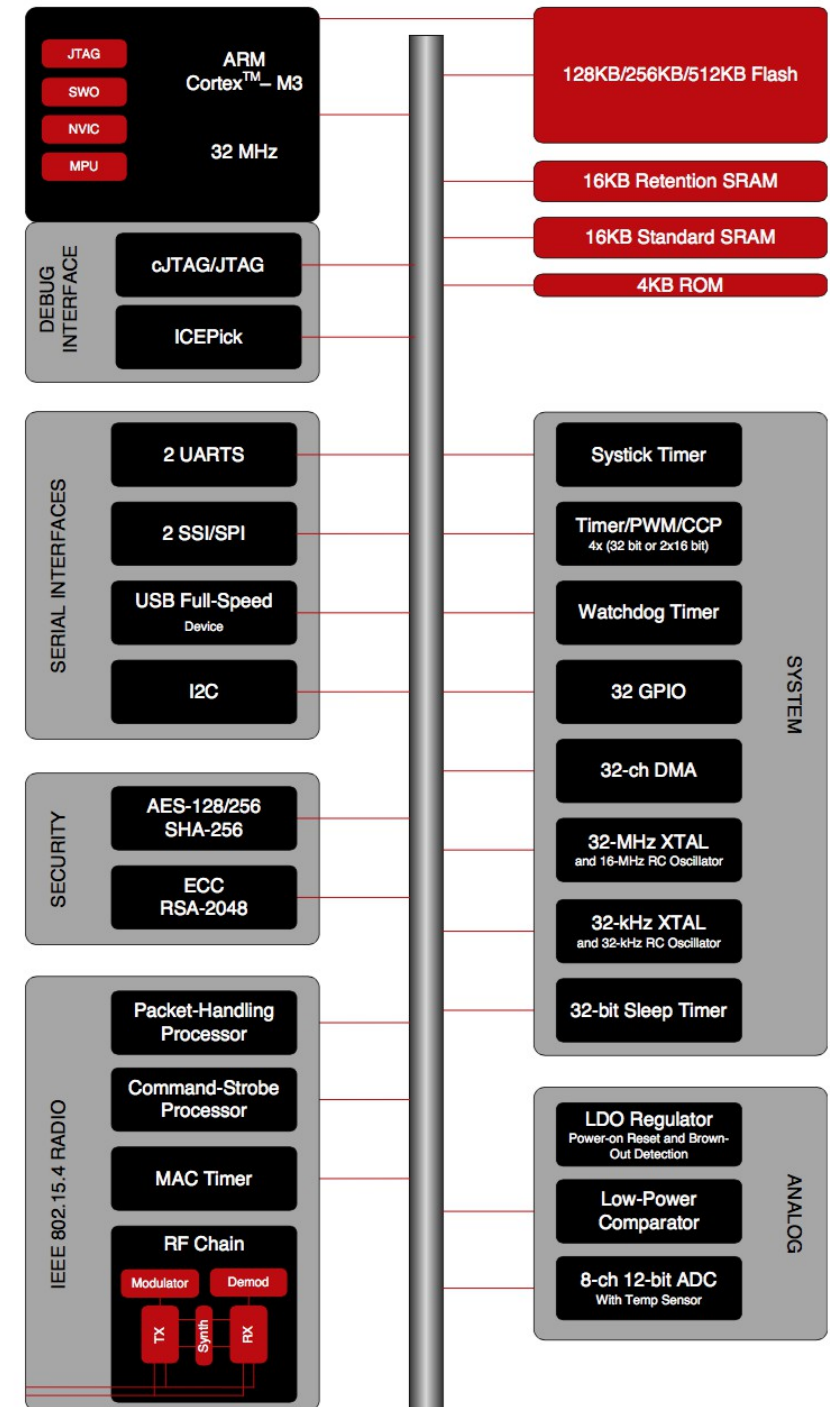
($V_{CC} = 2.7\text{ V}$, $T_A = 25^\circ\text{C}$, unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|---|---------------|-----|------|-----|---------------|
| Power Supply Current ($V_{BATT} + V_{DDINT}$) | $I_{leakage}$ | - | <1.0 | - | μA |
| Off | I_{CCH} | - | 3.0 | - | μA |
| Hibernate | I_{CCD} | - | 40 | - | μA |
| Doze (No CLKO) | I_{CCI} | - | 500 | - | μA |
| Idle | I_{CCT} | - | 34 | - | mA |
| Transmit Mode | I_{CCR} | - | 37 | - | mA |
| Receive Mode | | | | | |

| Mode | Definition | Transition Time To or From Idle |
|-----------|--|---------------------------------|
| Off | All IC functions Off, Leakage only. $\overline{\text{RST}}$ asserted. | 23.332 ms to Idle |
| Hibernate | Crystal Reference Oscillator Off. (SPI not functional.) IC Responds to $\overline{\text{ATTN}}$. | 18.332 ms to Idle |
| Doze | Crystal Reference Oscillator On but CLKO output available only if Register 7, Bit 9 = 1 for frequencies of 1 MHz or less. (SPI not functional.) Responds to $\overline{\text{ATTN}}$ and can be programmed to enter Idle State through an internal timer comparator. | 332 μs to Idle |
| Idle | Crystal Reference Oscillator On with CLKO output available. SPI active. | |
| Receive | Crystal Reference Oscillator On. Receiver On. SPI should not be accessed. | 144 μs from Idle |
| Transmit | Crystal Reference Oscillator On. Transmitter On. SPI should not be accessed. | 144 μs from Idle |

CC2538 System-on-Chip

- 2012
- IEEE 802.15.4 2003 radio
 - +7 dBm output power
 - transmit 24 mA @ 0dBm (2.0 – 3.6 V)
 - receive 20 mA
 - several power-down modes 1-500 μ A
- ARM Cortex-M3 32 MHz processor
 - 128 - 512 KB Flash
 - 16+16 KB RAM
- 32 MHz xtal / 16 MHz RC / 32 kHz xtal / 32 kHz RC
- \$5 in 1k quantities



Summary table

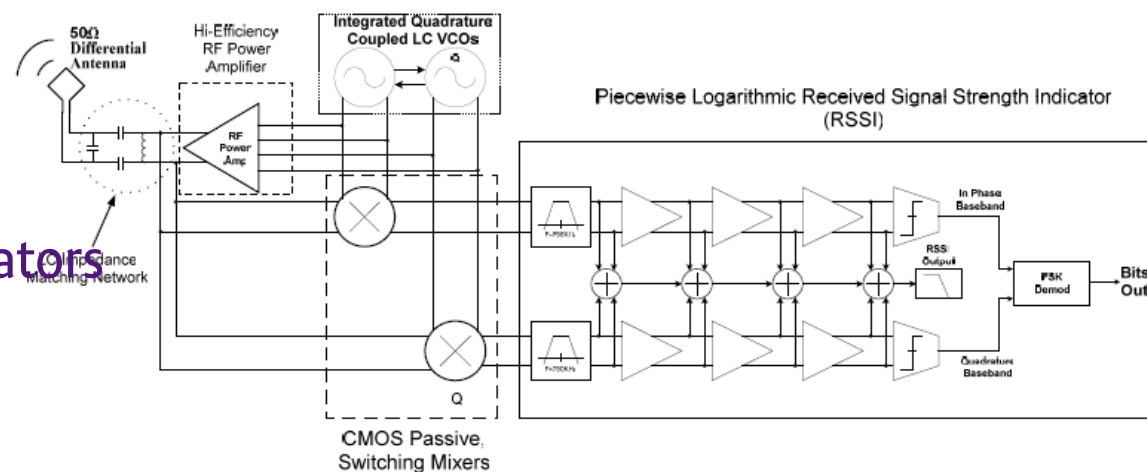
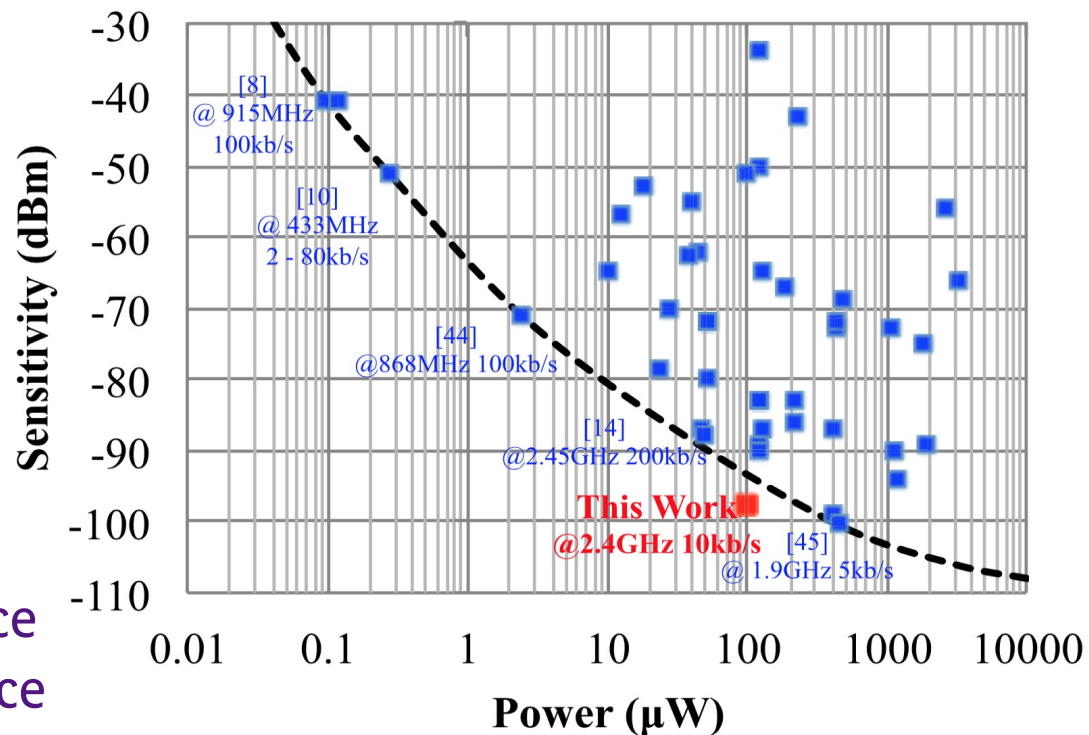
| | Band | Std | Rx current | Sensitivity | Tx current @ 0dBm |
|----------------|---------|--------------------|------------|---------------------------|-------------------|
| CC1021 (2003) | 868 MHz | FSK, GSK, OOK | 18 mA | ~ -110 dBm | 22 mA |
| CC1201 (2013) | 868 MHz | FSK, GSK, MSK, OOK | 19 – 23 mA | ~ -115 dBm | 28 mA |
| MC13192 (2003) | 2.4 GHz | IEEE 802.15.4 | 37 mA | -92 dBm | 34 mA |
| CC2538 (2012) | 2.4 GHz | IEEE 802.15.4 | 20 mA | - 96 dBm | 24 mA |
| LTC5800 (2013) | 2.4 GHz | IEEE 802.15.4 | 4.5 mA | - 93 dBm | 5.5 mA |
| SX1276 | 868 MHz | LoRa, FSK | 11 mA | -136/-118 dBm @ 125kHz BW | 20 mA @ +7dBm |

- Active power 10 – 100 mW
 - Duty cycling needed to meet long lifetime
- Long range = slow = high energy per bit (up to 1 mJ/bit)

Radio research

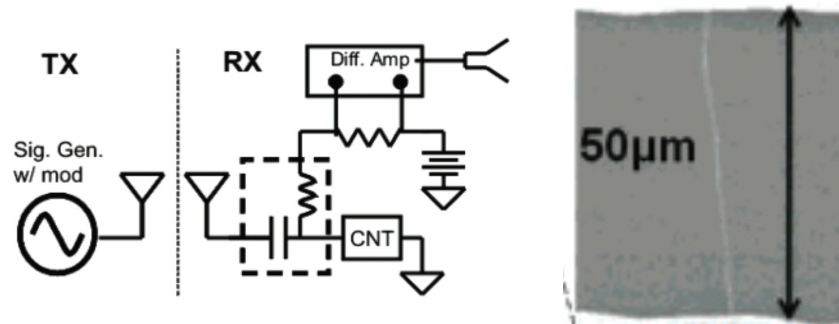
Research directions

- Wake-up radios
 - Lower sensitivity: non-detection
 - Interference: false positives
 - Separate frequency: different propagation
 - Same frequency: collision avoidance
 - IEEE 802.11ba, 5G wake-up sequence
- Ultra-low voltage design
 - Weak inversion mode
 - Use of switches for mixers
- Passive electronics
 - Micro-electromechanical resonators
- Passive transmitter
- UWB impulses, short times



Passive radios (1/2)

- *Passive receivers*
 - Galena (lead-sulfite) receivers (1894, J.C. Bose)
 - Single Carbon Nanotube receivers
 - NEMS/MEMS-based receivers
 - Passive mixers



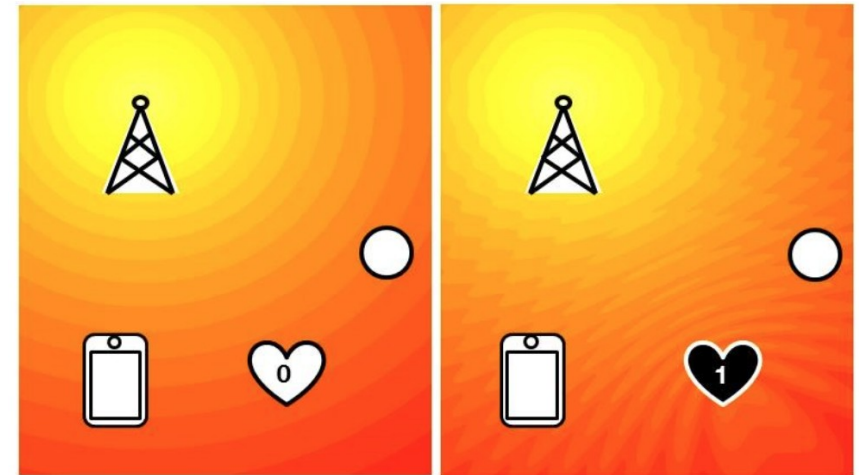
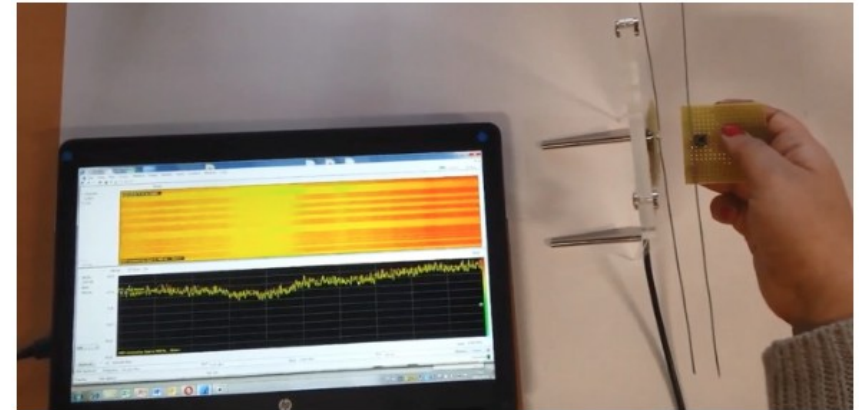
By Hihiman - Own work, CC BY-SA 3.0
<https://commons.wikimedia.org/w/index.php?curid=5228955>

Rutherglen C., Burke P., 2007, "Carbon Nanotube Radio". Nano Lett., 7 11 (November 2007), 32963299 , 0028-0836

Passive radios (2/2)

- *Passive transmitters*
 - Passive RFIDs
 - Illumination source can also be unknowing third party.
- **LoRaWAN passive transmitter**
 - 2.8 km range reported

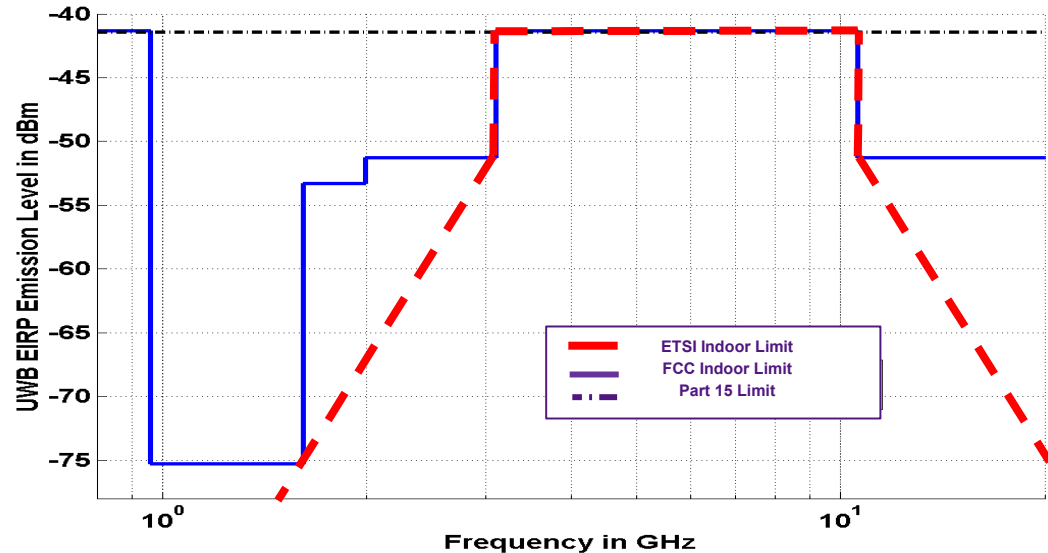
V. Talla, M. Hesar, B. Kellogg, A. Naja, J. R. Smith, S. Gollakota.
LoRa Backscatter: Enabling The Vision of Ubiquitous Connectivity. IMWUT, 2017



Ultra Wide Band

- Benefits

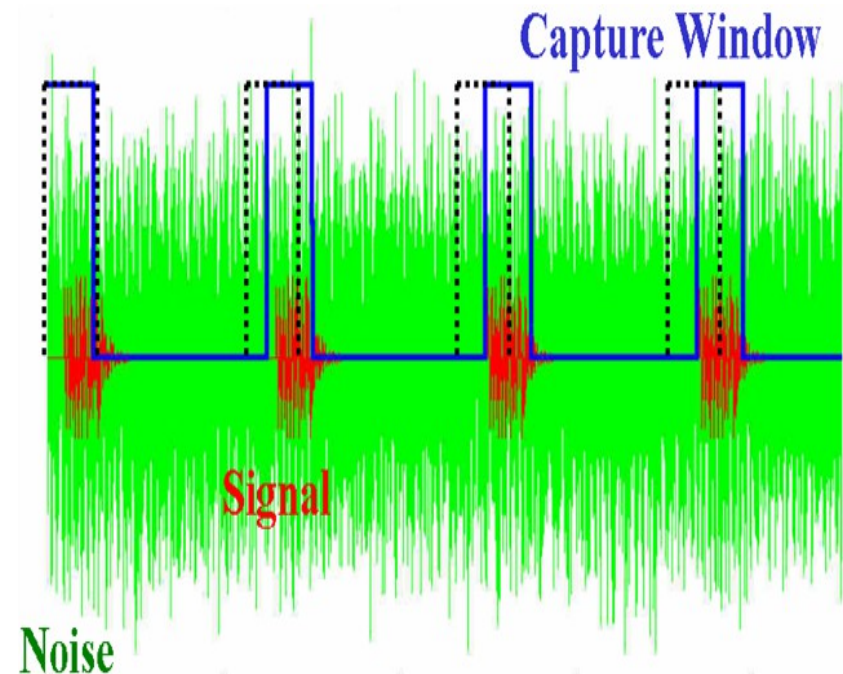
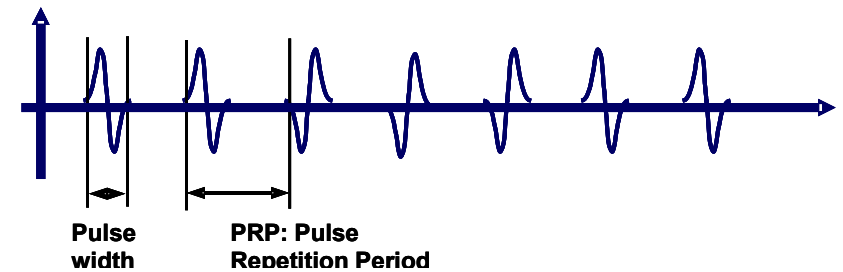
- Robust to narrow-band interference
- Robust to multipath
- Licence-free



- IEEE 802.15.4a Task Group, went into Revision 2007
 - 100 kbps – 6.8 Mbps, 100 m
 - Focus on low power radio, ranging
- A few chips available
 - BeSpoon.com (CEA-Leti spin-off), Decawave

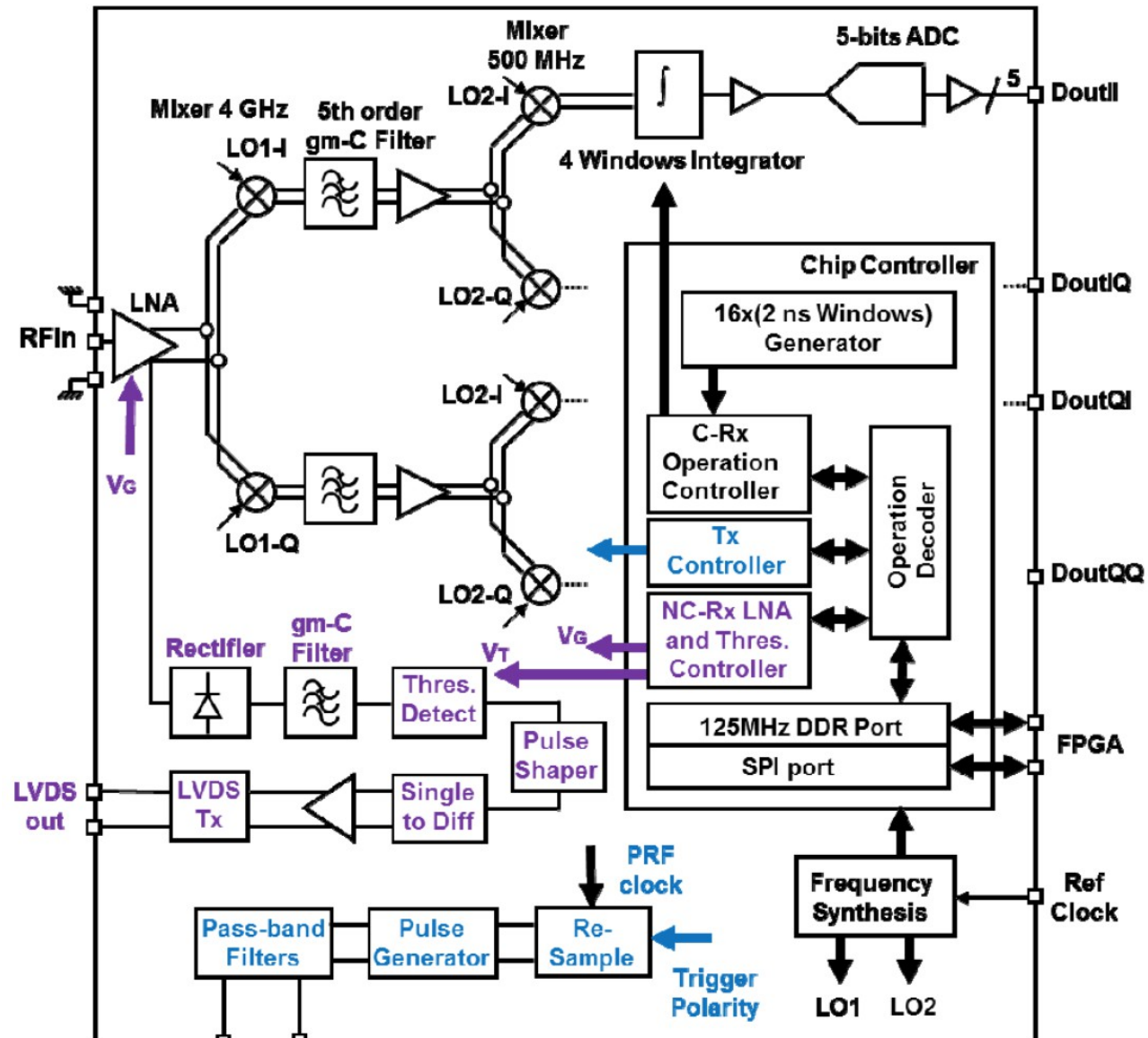
Ultra Wide Band impulse radio

- Transmission
 - 1 ns pulses, wideband
 - Pulse shaping, filtering
 - Time-dithering
 - On-Off, Polarity or Position modulation
- Reception
 - Expected pulse time windows
 - Coherent or non-coherent detection
 - Several pulses per bit of information
- Ranging
 - RF time of flight



Ultra Wide Band impulse radio

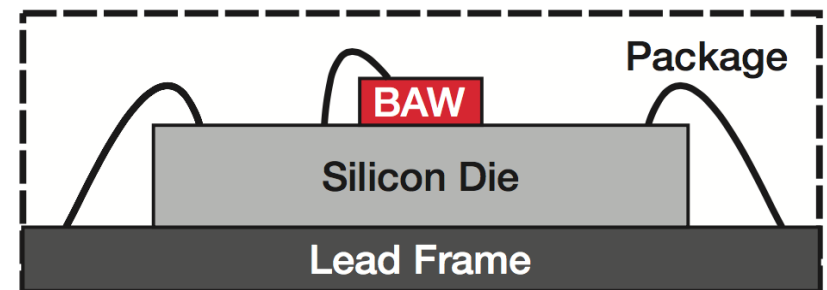
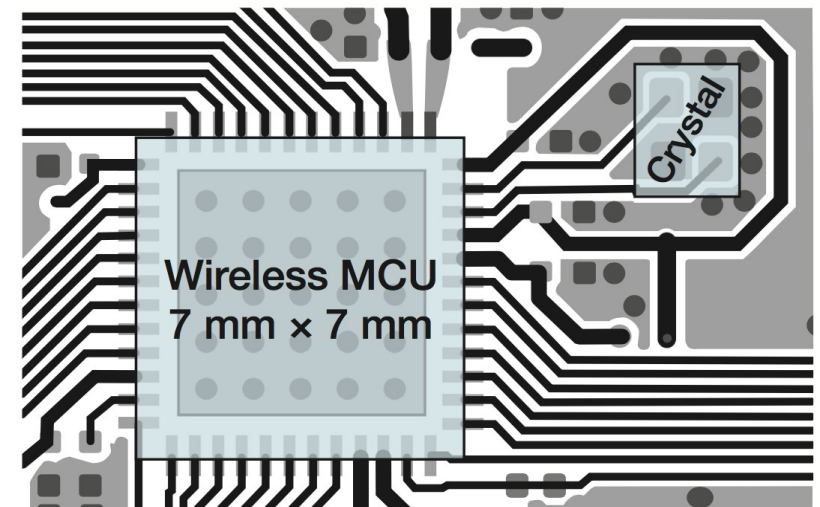
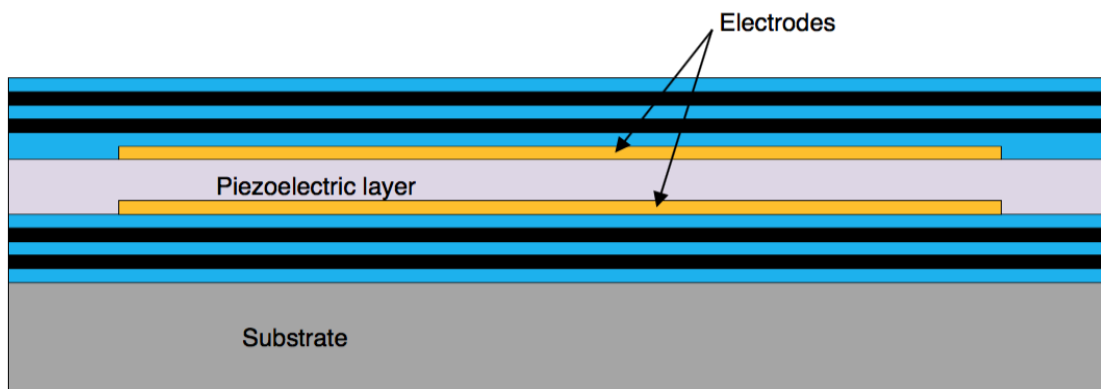
- Amenable to ultra low power consumption
 - very few linear circuits
 - idle most of the time
- Wideband electronics settles quickly
- Receiver circuits can be turned off between expected pulses
 - Including between multipath replicas



Ouvry, L.; Masson, G.; Pezzin, M.; Piaget, B.; Caillat, B.; Bourdel, S.; Dehaese, N.; Fourquin, O.; Gaubert, J.; Meillere, S.; Vauche, R., "A 4GHz CMOS 130 nm IR-UWB dual front-end transceiver for IEEE802.15 standards," Proceedings of the 21st IEEE International Conference on Electronics, Circuits and Systems (ICECS), pp.798,801, Marseille, France, Dec. 2014.

Cheaper radios (1/2)

- In-package Bulk Acoustic Wave (BAW) resonator
- TI CC2652RB (Feb 2019)
 - BT, 15.4 radio, Zigbee stack
 - 48 MHz BAW, 40 ppm accuracy



Cheaper radios (2/2)

- Crystal-less radio
 - Network-based synchronization
- On-chip antenna
 - Deemed viable above > 10 GHz

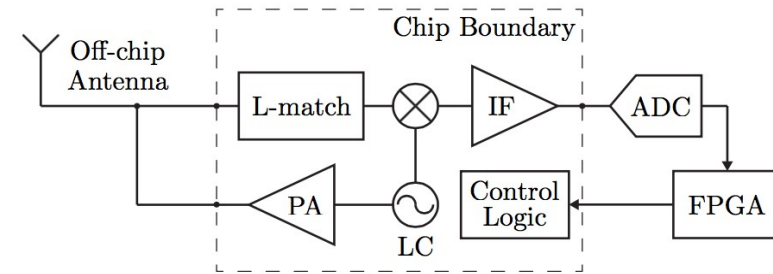
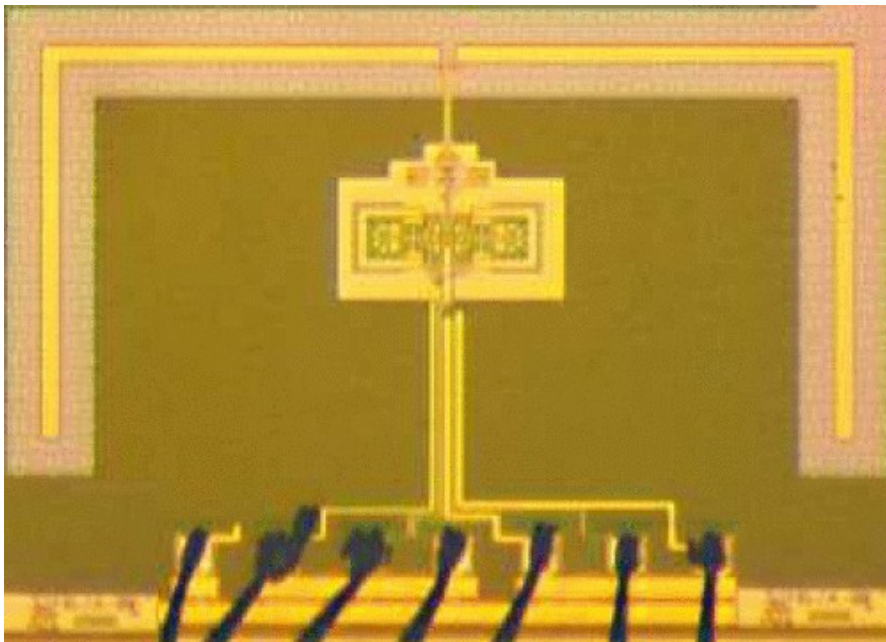


Fig. 1. System level block diagram of the transceiver.

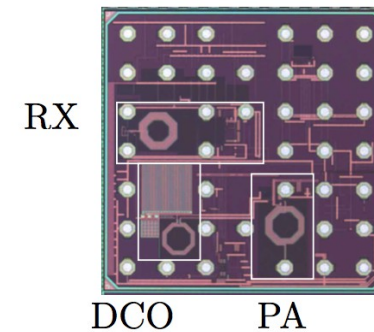


Fig. 2. Die photo of the 1.83 mm * 1.83 mm flip-chip IC, of which the radio occupies 1.2 mm².

B. Wheeler et al., "Crystal-free narrow-band radios for low-cost IoT," 2017 IEEE Radio Frequency Integrated Circuits Symposium (RFIC), Honolulu, HI, 2017, pp. 228-231. doi: 10.1109/RFIC.2017.7969059

M. Pons et al., "Study of on-chip integrated antennas using standard silicon technology for short distance communications," 2005 European Microwave Conference, Paris, 2005, pp. 4 pp.-1714.

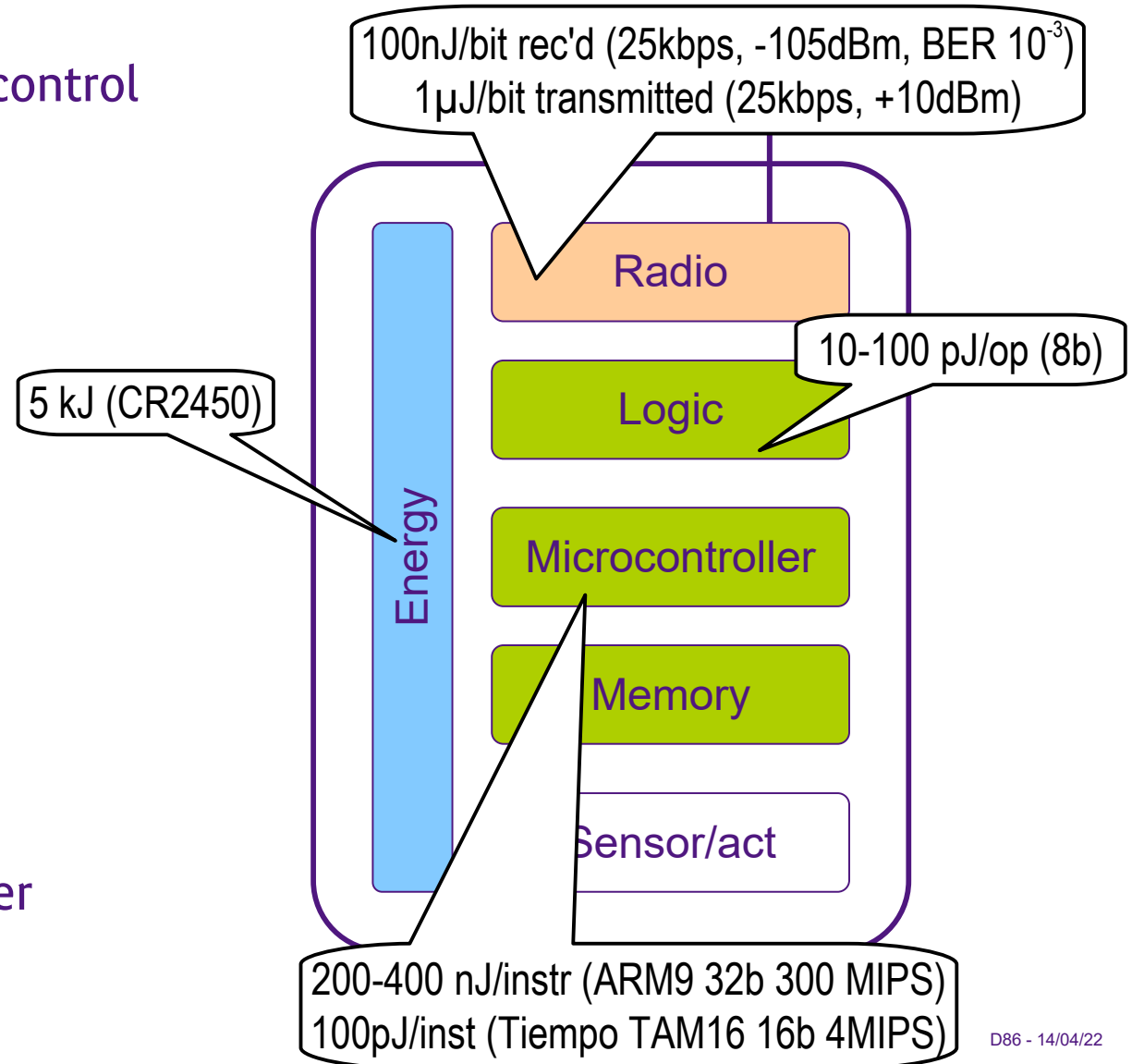
Agenda

- Introduction
- Some experimentation boards and platforms
- Energy source, energy consumption
- Microcontrollers, memory
- Spectrum, PHY layer and radio chips
- Conclusions

Conclusions

Sensor Node energy balance

- Energy
 - monitoring/conversion/control
 - battery
 - solar cell
 - vibrations
 - heat
- Radio
 - low power
 - highly efficient
 - unlicensed
- Computation
 - hard-wired
 - microprocessor/controller
- Sensing/Actuation



Transmission vs. Computation

- Wireless transmission = 0.1 μ J - 1mJ per bit
- Microcontroller computation = 0.1 - 10 nJ per instruction
- Saving 1 bit on the air is worth 100 computation instructions
- Trend to reducing communication cost
 - by using more computation
 - smart protocols, compression
- The opposite in wired (fiber) networks !

End of Session